

# **Space engineering**

# **Methods for the calculation of radiation received and its effects, and a policy for design margins**

**Corrigendum 1**

The following typographical error was identified in the published version of this document.

• Requirement [5.3c](#page-36-0) (page 37): The correct ECSS Standard called from requirement 5.3c is "ECSS-E-ST-10-04" and not as written "ECSS-E-ST-10-09".

NOTE:

For this error an ECSS Change Request was registered. The document has not been updated and still contains the typo.

> **ECSS Secretariat ESA-ESTEC Requirements & Standards Division Noordwijk, The Netherlands**



#### **Foreword**

This Standard is one of the series of ECSS Standards intended to be applied together for the management, engineering and product assurance in space projects and applications. ECSS is a cooperative effort of the European Space Agency, national space agencies and European industry associations for the purpose of developing and maintaining common standards. Requirements in this Standard are defined in terms of what shall be accomplished, rather than in terms of how to organize and perform the necessary work. This allows existing organizational structures and methods to be applied where they are effective, and for the structures and methods to evolve as necessary without rewriting the standards.

This Standard has been prepared by the ECSS-E-ST-10-12 Working Group, reviewed by the ECSS Executive Secretariat and approved by the ECSS Technical Authority.

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<span id="page-2-0"></span>

# **Change log**





# **Table of contents**













# **Figures**

[Figure 9-1: Procedure flowchart for hardness assurance for single event effects.](#page-79-0) ................80

### **Tables**





# **1 Scope**

<span id="page-7-0"></span>This standard is a part of the System Engineering branch of the ECSS engineering standards and covers the methods for the calculation of radiation received and its effects, and a policy for design margins. Both natural and manmade sources of radiation (*e.g.* radioisotope thermoelectric generators, or RTGs) are considered in the standard.

This standard applies to the evaluation of radiation effects on all space systems.

This standard applies to all product types which exist or operate in space, as well as to crews of manned space missions. The standard aims to implement a space system engineering process that ensures common understanding by participants in the development and operation process (including Agencies, customers, suppliers, and developers) and use of common methods in evaluation of radiation effects.

This standard is complemented by ECSS-E-HB-10-12 "Radiation received and its effects and margin policy handbook".

This standard may be tailored for the specific characteristic and constrains of a space project in conformance with ECSS-S-ST-00.





# **2 Normative references**

<span id="page-8-0"></span>The following normative documents contain provisions which, through reference in this text, constitute provisions of this ECSS Standard. For dated references, subsequent amendments to, or revision of any of these publications do not apply, However, parties to agreements based on this ECSS Standard are encouraged to investigate the possibility of applying the more recent editions of the normative documents indicated below. For undated references, the latest edition of the publication referred to applies.





# <span id="page-9-0"></span>**3 Terms, definitions and abbreviated terms**

# <span id="page-9-1"></span>**3.1 Terms from other standards**

For the purpose of this Standard, the terms and definitions from ECSS-ST-00-01 apply, in particular for the following terms:

**derating**

**subsystem**

### <span id="page-9-2"></span>**3.2 Terms specific to the present standard**

#### **3.2.1 absorbed dose**

energy absorbed locally per unit mass as a result of radiation exposure which is transferred through ionisation, displacement damage and excitation and is the sum of the ionising dose and non-ionising dose

- NOTE 1 It is normally represented by D, and in accordance with the definition, it can be calculated as the quotient of the energy imparted due to radiation in the matter in a volume element and the mass of the matter in that volume element. It is measured in units of gray, Gy  $(1 \text{ Gy} = 1 \text{ J kg}^{-1} (= 100 \text{ rad})).$
- NOTE 2 The absorbed dose is the basic physical quantity that measures radiation exposure.

#### **3.2.2 air kerma**

energy of charged particles released by photons per unit mass of dry air

NOTE It is normally represented by K.

#### **3.2.3 ambient dose equivalent, H\*(d)**

dose at a point equivalent to the one produced by the corresponding expanded and aligned radiation field in the ICRU sphere at a specific depth on the radius opposing the direction of the aligned field

- NOTE 1 It is normally represented by  $H^*(d)$ , where d is the specific depth used in its definition, in mm.
- NOTE 2 H\*(d) is relevant to strongly penetrating radiation. The value normally used is 10 mm,



but dose equivalent at other depths can be used when the dose equivalent at 10 mm provides an unacceptable underestimate of the effective dose.

#### **3.2.4 bremsstrahlung**

high energy electromagnetic radiation in the X-ray energy range emitted by charged particles slowing down by scattering off atomic nuclei

> NOTE The primary particle is ultimately absorbed while the bremsstrahlung can be highly penetrating. In space the most common source of bremsstrahlung is electron scattering.

#### **3.2.5 component**

device that performs a function and consists of one or more elements joined together and which cannot be disassembled without destruction

#### **3.2.6 continuous slowing down approximation range (CSDA)**

integral pathlength travelled by charged particles in a material assuming no stochastic variations between different particles of the same energy, and no angular deflections of the particles

#### **3.2.7 COTS**

commercial electronic component readily available off-the-shelf, and not manufactured, inspected or tested in accordance with military or space standards

#### **3.2.8 critical charge**

minimum amount of charge collected at a sensitive node due to a charged particle strike that results in a SEE

#### **3.2.9 cross-section**

<single event phenomena> probability of a single event effect occurring per unit incident particle fluence

> NOTE This is experimentally measured as the number of events recorded per unit fluence.

#### **3.2.10 cross-section**

<nuclear or electromagnetic physics> probability of a particle interaction per unit incident particle fluence

> NOTE It is sometimes referred to as the *microscopic cross-section*. Other related definition is the macroscopic cross section, defines as the probability of an interaction per unit pathlength of the particle in a material.



#### **3.2.11 directional dose equivalent**

dose at a point equivalent to the one produced by the corresponding expanded radiation field in the ICRU sphere at a specific depth d on a radius on a specified direction



radiation where a reference depth of 0,07 mm is usually used and the quantity denoted  $H'(0,07, Ω)$ .

#### **3.2.12 displacement damage**

crystal structure damage caused when particles lose energy by elastic or inelastic collisions in a material

#### **3.2.13 dose**

quantity of radiation delivered at a position

- NOTE 1 In its broadest sense this can include the flux of particles, but in the context of space energetic particle radiation effects, it usually refers to the energy absorbed locally per unit mass as a result of radiation exposure.
- NOTE 2 If "dose" is used unqualified, it refers to both ionising and non-ionising dose. Non-ionising dose can be quantified either through energy deposition via displacement damage or damage-equivalent fluence (see Clause [8\)](#page-62-0).

#### **3.2.14 dose equivalent**

absorbed dose at a point in tissue which is weighted by quality factors which are related to the LET distribution of the radiation at that point

#### **3.2.15 dose rate**

rate at which radiation is delivered per unit time

#### **3.2.16 effective dose**

sum of the equivalent doses for all irradiated tissues or organs, each weighted by its own value of tissue weighting factor

> NOTE 1 It is normally represented by E, and in accordance with the definition it is calculated with the equation below, and the  $wr$  is specified in the ICRP-92 standard [RDH.22]:

$$
E = \sum w_T \cdot H_T \tag{1}
$$

For further discussion on *E*, see ECSS-E-HB-10- 12 Section 10.2.2.



NOTE 2 Effective dose, like organ equivalent dose, is measured in units of sievert, Sv. Occasionally this use of the same unit for different quantities can give rise to confusion.

#### **3.2.17 energetic particle**

particle which, in the context of space systems radiation effects, can penetrate outer surfaces of spacecraft

#### **3.2.18 equivalent dose**

Se[e 3.2.41](#page-15-0) [\(organ equivalent dose\)](#page-15-0)

#### **3.2.19 equivalent fluence**

quantity which represents the damage at different energies and from different species by a fluence of monoenergetic particles of a single species

NOTE 1 These are usually derived through testing.

NOTE 2 Damage coefficients are used to scale the effect caused by particles to the damage caused by a standard particle and energy.

#### **3.2.20 extrapolated range**

range determined by extrapolating the line of maximum gradient in the intensity curve until it reaches zero intensity

#### **3.2.21 Firsov scattering**

the reflection of fast ions from a dense medium at glancing angles

NOTE See references [\[2\].](#page-103-0)

#### **3.2.22 fluence**

time-integration of flux

NOTE It is normally represented by *Φ.*

#### **3.2.23 flux**

<unidirectional incident particles> number of particles crossing a surface at right angles to the particle direction, per unit area per unit time

#### **3.2.24 flux**

<arbitrary angular distributions> number of particles crossing a sphere of unit cross-sectional area (i.e. of radius  $1/\sqrt{\pi}$ ) per unit time

- NOTE 1 For arbitrary angular distributions, it is normally known as omnidirectional flux.
- NOTE 2 Flux is often expressed in "integral form" as particles per unit time (e.g. electrons  $cm<sup>2</sup> s<sup>-1</sup>$ ) above a certain energy threshold.
- NOTE 3 The directional flux is the differential with respect to solid angle (e.g. particles-cm- $2$ steradian $-1s$ <sup>-1</sup>) while the "differential" flux is



differential with respect to energy (e.g. particles-cm-2MeV-1s-1). In some cases fluxes are treated as a differential with respect to linear energy transfer rather than energy.

#### **3.2.25 ICRU sphere**

sphere of 30 cm diameter made of ICRU soft tissue

NOTE This definition is provided by the International Commission of Radiation Units and Measurements Report 33 [\[12\].](#page-103-1)

#### **3.2.26 ICRU Soft Tissue**

tissue equivalent material with a density of  $1 \text{ g/cm}^3$  and a mass composition of 76,2 % oxygen, 11,1 % carbon, 10,1 % hydrogen and 2,6 % nitrogen.

> NOTE This definition is provided in the ICRU Report 33 [\[12\].](#page-103-1)

#### **3.2.27 ionising dose**

amount of energy per unit mass transferred by particles to a target material in the form of ionisation and excitation

#### **3.2.28 ionising radiation**

transfer of energy by means of particles where the particle has sufficient energy to remove electrons, or undergo elastic or inelastic interactions with nuclei (including displacement of atoms), and in the context of this standard includes photons in the X-ray energy band and above

#### **3.2.29 isotropic**

property of a distribution of particles where the flux is constant over all directions

#### **3.2.30 L or L-shell**

parameter of the geomagnetic field often used to describe positions in near-Earth space

> NOTE L or L-shell has a complicated derivation based on an invariant of the motion of charged particles in the terrestrial magnetic field. However it is useful in defining plasma regimes within the magnetosphere because, for a dipole magnetic field, it is equal to the geocentric altitude in Earth-radii of the local magnetic field line where it crosses the equator.

#### **3.2.31 linear energy transfer (LET)**

rate of energy deposited through ionisation from a slowing energetic particle with distance travelled in matter, the energy being imparted to the material

> NOTE 1 LET is normally used to describe the ionisation track caused due to the passage of an ion. LET



is material dependent and is also a function of particle energy and charge. For ions involved in space radiation effects, it increases with decreasing energy (it also increases at high energies, beyond the minimum ionising energy). LET allows different ions to be considered together by simply representing the ion environment as the summation of the fluxes of all ions as functions of their LETs. This simplifies single-event upset calculation. The rate of energy loss of a particle, which also includes emitted secondary radiations, is the stopping power.

NOTE 2 LET is not equal to (but is often approximated to) particle electronic stopping power, which is the energy loss due to ionisation and excitation per unit pathlength.

#### **3.2.32 LET Threshold**

minimum LET that a particle should have to cause a SEE in a circuit when going through a device sensitive volume

#### **3.2.33 margin**

factor or difference between the design environment specification for a device or product and the environment at which unacceptable behaviour occurs

#### <span id="page-14-0"></span>**3.2.34 mean organ absorbed dose**

energy absorbed by an organ due to ionising radiation divided by its mass

NOTE It is normally represented by DT, and in accordance with the definition, it is calculated with the equation (35) in ECSS-E-HB-10-12 Section 10.2.2. The unit is the gray (Gy), being  $1$  Gy = 1 joule / kg.

#### **3.2.35 mean range**

integral pathlength travelled by particles in a material after which the intensity is reduced by a factor of *e* ≈ 2,7183

> NOTE In accordance with the above definition, it is not the range at which all particles are stopped.

#### **3.2.36 multiple bit upset (MBU)**

set of bits corrupted in a digital element that have been caused by direct ionisation from a single traversing particle or by recoiling nuclei and/or secondary products from a nuclear interaction

NOTE MCU and SMU are special cases of MBU.



#### **3.2.37 multiple cell upset (MCU)**

set of physically adjacent bits corrupted in a digital element that have been caused by direct ionisation from a single traversing particle or by recoiling nuclei from a nuclear interaction

#### **3.2.38 (total) non-ionising dose, (T)NID, or non-ionising energy loss (NIEL) dose**

energy absorption per unit mass of material which results in damage to the lattice structure of solids through displacement of atoms

> NOTE Although the SI unit of TNID or NIEL dose is the gray (see definition [3.2.34\)](#page-14-0), for spacecraft radiation effects, MeV/g(material) is more commonly used in order to avoid confusion with ionising energy deposition, *e.g.* MeV/g(Si) for TNID in silicon.

#### **3.2.39 NIEL or NIEL rate or NIEL coefficient**

rate of energy loss in a material by a particle due to displacement damage per unit pathlength

#### **3.2.40 omnidirectional flux**

scalar integral of the flux over all directions

NOTE This implies that no consideration is taken of the directional distribution of the particles which can be non-isotropic. The flux at a point is the number of particles crossing a sphere of unit cross-sectional surface area (i.e. of radius 1/  $\pi$ ) per unit time. An omnidirectional flux is not to be confused with an isotropic flux.

#### <span id="page-15-0"></span>**3.2.41 organ equivalent dose**

sum of each contribution of the absorbed dose by a tissue or an organ exposed to several radiation types, weighted by the each radiation weighting factor for the radiations impinging on the body

> NOTE 1 The organ equivalent dose, an ICRP-60 [\[11\]](#page-103-2) defined quantity, is normally represented by HT, and usually shortened to **equivalent dose.** In accordance with the definition, it is calculated with the equation below (for further discussion, see ECSS-E-HB-10-12 Section 10.2.2):

$$
H_T = \sum w_R \cdot D_{T,R} \tag{2}
$$

NOTE 2 The organ equivalent dose is measured in units of sievert, Sv, where  $1 Sv = 1$  J/kg. The unit rem (roentgen equivalent man) is still used, where  $1 Sv = 100 rem.$ 



#### **3.2.42 personal dose equivalent (individual dose equivalent)**

dose equivalent in ICRU soft tissue at a depth in the body

- NOTE 1 The personal dose equivalent, and ICRU quantity, is normally represented by  $H_P(d)$  for strongly penetrating radiation at a depth d in millimetres that is appropriate for strongly penetrating radiation. A reference depth of 10 mm is usually used. It varies both as a function of individuals and location and is appropriate for organs and tissues deeply situated in the body.
- NOTE 2 It is normally represented by  $H<sub>s</sub>(d)$  for weakly penetrating radiation (superficial) at a depth d in millimetres that is appropriate for weakly penetrating radiation. A reference depth of 0,07 mm is usually used. It varies both as a function of individuals and location and is appropriate for superficial organs and tissues which are going to be irradiated by both weakly and strongly penetrating radiation.

#### **3.2.43 plasma**

partly or wholly ionised gas whose particles exhibit collective response to magnetic or electric fields

> NOTE The collective motion is brought about by the electrostatic Coulomb force between charged particles. This causes the particles to rearrange themselves to counteract electric fields within a distance of the order of the Debye length. On spatial scales larger than the Debye length plasmas are electrically neutral.

#### **3.2.44 projected range**

average depth of penetration of a particle measured along the initial direction of the particle

#### **3.2.45 quality factor**

factor accounting for the different biological efficiencies of ionising radiation with different LET, and used to convert the absorbed dose to operational parameters (ambient dose equivalent, directional dose equivalent and personal dose equivalent)

> NOTE 1 Quality factor, normally represented by Q, are used (rather than radiation or tissue weighting factors) to convert the absorbed dose to dose equivalent quantities described above (ambient dose equivalent, directional dose equivalent and personal dose equivalent). Its actual values are given by ICRP-6[0 \[11\]](#page-103-2) (see [11.2.3.2\)](#page-98-2).



NOTE 2 Prior to ICRP-60 [\[11\],](#page-103-2) quality factors were synonymous to radiation weighting factors.

#### **3.2.46 radiation**

transfer of energy by means of a particle (including photons)

NOTE In the context of this Standard, electromagnetic radiation below the X-ray band is excluded. This therefore excludes UV, visible, thermal, microwave and radiowave radiation.

#### **3.2.47 radiation design margin (RDM)**

<cumulative process> ratio of the radiation tolerance or capability of the component, system or protection limit for astronaut, to the predicted radiation environment for the mission or phase of the mission

#### <span id="page-17-0"></span>**3.2.48 radiation design margin (RDM)**

<non-destructive single event> ratio of the design SEE tolerance to the predicted SEE rate for the environment

> NOTE The design SSE tolerance is the acceptable SEE rate which the equipment or mission can experience while still meeting the equipment reliability and availability requirements.

#### <span id="page-17-1"></span>**3.2.49 radiation design margin (RDM)**

<destructive single event> ratio of the acceptable probability of component failure by the SEE mechanism to the calculated probability of failure

> NOTE the acceptable probability of component failure is based on the equipment reliability and availability specifications.

#### **3.2.50 radiation design margin (RDM)**

<biological effect> ratio of the protection limits defined by the project for the mission to the predicted exposure for the crew

#### **3.2.51 radiation weighting factor**

factor accounting for the different levels of radiation effects in biological material for different radiations at the same absorbed dose

> NOTE It is normally represented by WR. Its value is defined by ICRP (see claus[e 11.2.2.2\)](#page-96-1).

#### **3.2.52 relative biological effectiveness (RBE)**

inverse ratio of the absorbed dose from one radiation type to that of a reference radiation that produces the same radiation effect

NOTE The component tolerance or capability, above which its performance becomes non-compliant, is project-defined.



- NOTE 1 The radiation type is usually <sup>60</sup>Co or 200-250 keV X-rays.
- NOTE 2 In contrast to the weighting or quality factors, RBE is an empirically founded measurable quantity. For additional information on RBE, see ECSS-E-HB-10-12 Section 10.2.2.

#### **3.2.53 sensitive volume (SV)**

charge collection region of a device

#### **3.2.54 single event burnout (SEB)**

destructive triggering of a vertical n-channel transistor or power NPN transistor accompanied by regenerative feedback

#### **3.2.55 single event dielectric rupture (SEDR)**

formation of a conducting path triggered by a single ionising particle in a highfield region of a dielectric

NOTE For example, in linear devices, or in FPGAs.

#### **3.2.56 single event disturb (SED)**

momentary voltage excursion (voltage spike) at a node in an integrated circuit, originally formed by the electric field separation of the charge generated by an ion passing through or near a junction

> NOTE SED is similar to SET, but used to refer to such events in digital microelectronics.

#### **3.2.57 single event effect (SEE)**

effect caused either by direct ionisation from a single traversing particle or by recoiling nuclei emitted from a nuclear interaction

#### **3.2.58 single event functional interrupt (SEFI)**

interrupt caused by a single particle strike which leads to a temporary nonfunctionality (or interruption of normal operation) of the affected device

#### **3.2.59 single event gate rupture (SEGR)**

formation of a conducting path triggered by a single ionising particle in a highfield region of a gate oxide

#### **3.2.60 single event hard error (SEHE)**

unalterable change of state associated with semi-permanent damage to a memory cell from a single ion track

#### **3.2.61 single event latch-up (SEL)**

potentially destructive triggering of a parasitic PNPN thyristor structure in a device



#### **3.2.62 single event snapback (SESB)**

event that occurs when the parasitic bipolar transistor that exists between the drain and source of a MOS transistor amplifies the avalanche current that results from a heavy ion

#### **3.2.63 single event transient (SET)**

momentary voltage excursion (voltage spike) at a node in an integrated circuit, originally formed by the electric field separation of the charge generated by an ion passing through or near a junction

#### **3.2.64 single event upset (SEU)**

single bit flip in a digital element that has been caused either by direct ionisation from a traversing particle or by recoiling nuclei emitted from a nuclear interaction

#### **3.2.65 single word multiple bit upset (SMU)**

set of logically adjacent bits corrupted in a digital element caused by direct ionisation from a single traversing particle or by recoiling nuclei from a nuclear interaction

> NOTE SMU are multiple bit upsets within a single data word.

#### **3.2.66 solar energetic particle event (SEPE)**

emission of energetic protons or heavier nuclei from the Sun within a short space of time (hours to days) leading to particle flux enhancement

> NOTE SEPE are usually associated with solar flares (with accompanying photon emission in optical, UV and X-Ray) or coronal mass ejections.

#### **3.2.67 stopping power**

average rate of energy-loss by a given particle per unit pathlength traversed through a given material

- NOTE The following are consequence of the above definition:
	- **collision stopping power**: (electrons and positrons) average energy loss per unit pathlength due to inelastic Coulomb collisions with bound atomic electrons resulting in ionisation and excitation.
	- **radiative stopping power**: (electrons and positrons) average energy loss power unit pathlength due to emission of bremsstrahlung in the electric field of the atomic nucleus and of the atomic electrons.
	- **electronic stopping power**: (particles heavier than electrons) average energy loss



per unit pathlength due to inelastic Coulomb collisions with atomic electrons resulting in ionisation and excitation.

• **nuclear stopping power**: (particles heavier than electrons) average energy loss per unit pathlength due to inelastic and elastic Coulomb collisions with atomic nuclei in the material.

#### **3.2.68 tissue weighting factor**

factor that accounts for the different sensitivity of organs or tissue in expressing radiation effects to the same equivalent dose

> NOTE It is normally represented by  $wr$ , and its actual values are defined by ICRP (see clause [11.2.2.3\)](#page-97-2).

#### **3.2.69 total ionising dose**

energy deposited per unit mass of material as a result of ionisation

NOTE The SI unit is the gray (see definition [3.2.34\)](#page-14-0). However, the deprecated unit rad (radiation absorbed dose) is still used frequently (1 rad =  $1 cGy$ ).

### <span id="page-20-0"></span>**3.3 Abbreviated terms**

For the purpose of this Standard, the abbreviated terms from ECSS-S-ST-00-01 and the following apply:

























# **4 Principles**

# <span id="page-26-1"></span><span id="page-26-0"></span>**4.1 Radiation effects**

This standard is applicable to all space systems. There is no space system in which radiation effects can be neglected.

In this clause the word "component" refers not only to electronic components but also to other fundamental constituents of space hardware units and subsystems such as solar cells, optical materials, adhesives, and polymers.

Survival and successful operation of space systems in the space radiation environment, or the surface of other solar system bodies cannot be ensured without careful consideration of the effects of radiation. A comprehensive compendium of radiation effects is provided in ECSS-E-HB-10-12 Section 3. The corresponding engineering process, including design of units and sub-systems, involves several trade-offs, one of which is radiation susceptibility. Some radiation effects can be mission limiting where they lead to a prompt or accumulated degradation which results in subsystem or system failure, or catastrophic system anomalies. Examples are damage of electronic components due to total ionising dose, or damaging interaction of a single heavy ion (thermal failure following "latch-up"). Others effects can be a source of interference, degrading the efficiency of the mission. Examples are radiation "background" in sensors or corruption of electronic memories. Biological effects are also important for manned and some other missions where biological samples are flown.

The correct evaluation of radiation effects occurs as early as possible in the design of systems, and is repeated throughout the development phase. A radiation environment specification is established and maintained as a mandatory element of any procurement actions from the start of a project (Pre-Phase A or other orbit trade-off pre-studies). The specification is specific to the mission and takes account of the timing and duration of the mission, the nominal and transfer trajectories, and activities on non-terrestrial solar system bodies, employing the methods defined in ECSS-E-ST-10-04. Upon any update to the radiation environment specification (*e.g.* as a result of orbit changes), a complete re-evaluation of the radiation effects calculations arising from this standard is performed.

In order to make a radiation effects evaluation, test data are used, both to confirm the compatibility of the component with the environment it is intended to operate in, and to provide data for quantitative analysis of the radiation effect. In general there is one effects parameter for each radiation effect. Severe engineering, schedule and cost problems can result from inadequate



anticipation of space radiation effects and preparation of the engineering options and solutions.

In some cases, knowledge about the radiation effects on a particular component type can be found in the published literature or in databases on radiation effects. It is important to use these data with extreme caution since verifying that data are relevant to the actual component being employed is often very difficult. For example in evaluating electronic components, consideration is given to:

- variations in sensitivity between manufacturers' "batches";
- variations in sensitivity within a nominally identical manufacturing "batch";
- changes in manufacturing, processes, packaging;
- correlation of measurements made on the ground and in-flight experience is far from complete.

As a consequence, and to account for accumulated uncertainties in testing procedures, component-to-component variations and environmental uncertainties, margins are usually applied to the radiation effects parameters for the particular mission. This document also seeks to provide specification for when and how to apply such margins.

Application of margins can have important effects on the engineering. Too high a level, implying a severe environment, can imply change of components (leading to increased cost or degradation of performance), application of additional shielding or even orbit changes. On the other hand, too low a margin can result in compromised mission performance or premature failure.

# <span id="page-27-0"></span>**4.2 Radiation effects evaluation activities**

[Table 4-1](#page-28-0) summarises the activities to be undertaken during a project. Effects on electrical and electronic systems, and materials are considered in terms of total ionising dose (TID), displacement damage, and single event effects (SEE). For spacecraft sensors, whether as part of the platform or payload, radiationenhanced background levels are also considered. The user can find a general description of these radiation effects in ECSS-E-HB-10-12 Section 3. [Table 4-2](#page-29-0) provides a summary, identifying the parameters used to quantify radiation effects, units and space radiation sources which induce those effects, whilst [Table 4-3](#page-30-0) identifies the effects as a function of component technology.



# **Table 4-1: Stages of a project and radiation effects analyses performed**

<span id="page-28-0"></span>



<span id="page-29-0"></span>

### **Table 4-2: Summary of radiation effects parameters, units and examples**



# <span id="page-30-0"></span>**Table 4-3: Summary of radiation effects and cross-references to other chapters**









<sup>a</sup> MEMS refers to the effects on the microelectromechanical structure only. Any surrounding microelectronics are also subject to other radiation effects identified in "Integrated circuits" row

<sup>b</sup> Se[e Table 8-1,](#page-66-0) "Radiation Detectors" for examples of semiconductor materials that are susceptible to γ-rays.

<sup>C</sup> The effect on scintillators refers primarily to the detector material registering the radiation. The electronics needed for readout can need additional radiation assessment.



# <span id="page-32-0"></span>**4.3 Relationship with other standards**

There are important relationships between this standard and others in the ECSS system and elsewhere. While these are referred to in the relevant parts of the standard, and referenced as mandatory references, some of the important complementary resources are briefly described here:

• ECSS-E-ST-10-04 "Space engineering - Space environment"

This standard describes the environment and specifies the methods and models to be employed in analysing and specifying the model.

• ECSS-Q-ST-60 "Space product assurance – Electrical, electronic and electromagnetic (EEE) components"

This standard identifies the requirements related to procurement and testing of electronic components, excluding solar cells.

• ECSS-E-ST-20 "Space engineering - Electrical and electronic"

This standard describes and sets up rules and regulations on generic system testing.

• ECSS-E-ST-10-11 "Space engineering - Human factors engineering"

This standard addresses all aspects relevant to assure a safe and comfortable environment for human beings undertaking a space mission. When other forms of life are accommodated on board, this standard also ensures the appropriate environmental conditions to those living organisms.

- ECSS-E-ST-34 "Space engineering Environmental control and life support"
- ECSS-E-ST-32-08 "Space engineering Materials"

This standard defines the mechanical engineering requirements for materials. It also encompasses the effects of the natural and induced environments to which materials used for space applications can be subjected.

• ECSS-Q-ST-30-11 "Space product assurance – Derating – EEE components"

This standard specifies derating requirements applicable to electronic, electrical and electro-mechanical components.

• ECSS-E-ST-20-08 "Space engineering - Photovoltaic assemblies and components"

This standard outlines the requirements for the qualification, procurement, storage and delivery of the main assemblies and components of the space solar array electrical layout: photovoltaic assemblies, solar cell assemblies, bare solar cells and cover-glasses. It does not outline requirements for the qualification, procurement, storage and delivery of the solar array structure and mechanism.



# **5 Radiation design margin**

# <span id="page-33-2"></span><span id="page-33-1"></span><span id="page-33-0"></span>**5.1 Overview**

### **5.1.1 Radiation environment specification**

The radiation environment specification forms part of the product requirements. Qualification margins (the required minimum RDM) are part of the specification, since the objective of the qualification process is to demonstrate whether an entity is capable of fulfilling the specified requirements, including the qualification margin in ECSS-S-ST-00-01. As a result of this qualification process, the achieved RDM is established, to be compared with the required RDM.

This Clause specifies requirements for addressing and establishing RDMs. Margins are closely related to hardness assurance as well as to environment uncertainties. Hardness assurance is covered in ECSS-Q-ST-60, and environment uncertainties and worst-case scenarios are specified in ECSS-E-ST-10-04.

### <span id="page-33-3"></span>**5.1.2 Radiation margin in a general case**

RDM can be specified at system level down to subsystem, board or component level, depending upon the local radiation environment specification at different components, and the effects analysis methodology adopted for the equipment.

Requiring the RDM to exceed a minimum value ensures that allowance is made for the uncertainties in the prediction of the radiation environment and damage effects, these arising from:

- Uncertainties in the models and data used to predict the environment;
- The potential for stochastic enhancements over the average environment (such as enhancements of the outer electron radiation belt);
- Systematic and statistical errors in models used to assess the influence of shielding, and determine radiation parameters (*e.g.* TID, TNID, particle fluence) at components' locations;
- Uncertainties in the radiation tolerance of components, established by irradiation tests, due to systematic testing errors;



• Uncertainties as a result of relating test data to the actual parts procured, and variability of measured radiation tolerance within the population of parts.

An appropriate selection of the radiation design margin takes into account:

- the criticality of the component, subsystem or system to the success of the mission, imposed through equipment reliability and availability requirements, and
- the type of mission (*e.g.* scientific, commercial, "low-cost", an optional mission extension).

Margins are also achieved by application of worst-case analyses. The quantification of the margins achieved is a good engineering practice. However, it is recognized that such a quantification is sometimes difficult or impossible.

### <span id="page-34-0"></span>**5.1.3 Radiation margin in the case of single events**

RDMs are usually related to cumulative degradation processes although within this document they are also used in the context of single event effects (SEE). In such context, the definition of RDM is adapted differently for the two separate cases of destructive or non-destructive single events (see definitions [3.2.48](#page-17-0) and [3.2.49\)](#page-17-1).

Since in the case of SEE the RDM definition can be linked to the SEE rate or risk, the RDM can change depending upon the phase of the mission (*e.g.* whether a payload system is intended to be operational at particular times) and local environment or space weather conditions (*e.g.* if the spacecraft is passing through the South Atlantic anomaly or during a solar particle event). Since SEE rate or risk prediction is based on use of test data and simplifying assumptions on the geometry and interactions, it is important to take into account the potential for large errors in predicting SEE rates when establishing the reliability requirements for equipment, and especially for critical equipment. Derating can also be used to reduce or remove susceptibility to SEE.

# <span id="page-34-1"></span>**5.2 Margin approach**

- a. The customer shall specify minimum RDMs (MRDMs) for the various radiation effects.
	- NOTE 1 The customer and supplier can agree to other margins to reflect conducted testing (e.g. supplier-performed lot acceptance tests, published tests on similar components) in specific cases and in accordance with the hardness assurance programme defined according to ECSS-Q-ST-60. These minimum RDMs can be established directly by the customer, or based on a proposal made by the supplier and approved by the customer.



NOTE 2 The margins for SEE are based on the consideration of acceptable risks and rates and are therefore involve system level considerations.

b. The achieved RDM shall be established by analysis and a justification provided in the applicable radiation hardness assurance programme required by ECSS-Q-ST-60 for Class 1, 2 and 3 components.

NOTE For RDM, see Clause [5.1.1.](#page-33-2)

- c. The analysis specified in requirement [5.2b](#page-34-1) shall include the following elements, and the associated uncertainties and margins, either hidden or explicit:
	- 1. Space radiation environment, evaluated as specified in clause [5.3.](#page-36-1)
	- 2. Deposited dose, calculated as specified in clause [5.4,](#page-37-0) and including:
		- (a) Shielding and
		- (b) Calculation of effects parameters
			- NOTE For example, ionising dose, displacement dose, SEE rate, instrumental background, and biological effects.
	- 3. Radiation effect behaviour of entities (including components, payloads, and humans), evaluated as specified in claus[e 5.5.](#page-37-1)
		- NOTE Hidden margins appear in many aspects of the hardness assurance process (see also the clauses of ECSS-Q-ST-60 relevant to "Radiation hardness") and they can compensate for uncertainties in other elements of the assessment process. The hardness assurance plan can consider:
			- Part type sensitivity evaluation.
			- Lot-to-lot variation.
			- Worst-case analysis
			- Minimum considered radiation level (since dose-depth curves are often asymptotic to a dose value for thick shielding due to bremsstahlung or high energy protons, a minimum qualification dose can be specified)
- d. For those elements in the design margin analysis, as specified in requirement [5.2c,](#page-34-1) that assume the following worst case conditions, their contribution to the design margin need not be applied:
	- 1. For environment, those specified as worst-case in ECSS-E-ST-10-04, Clause 9.
	- 2. For other than environment, those specified in clauses [5.4](#page-37-0) and [5.5.](#page-37-1)


- e. It shall be ensured that the qualification process demonstrates that the RDMs meet the MRDMs for the design adopted.
	- NOTE With this objective, the minimum radiation design margins specified for the equipment are established based on the reliability and availability requirements, and on the methodologies adopted for calculating the radiation environment and effects.

### <span id="page-36-0"></span>**5.3 Space radiation environment**

- a. When using the AE-8 model for electrons at the worst-case longitude on geostationary orbit for long-term exposure (greater than 11 years), no additional margin shall be applied.
- b. When using the AE-8 model under conditions other than specified in requirement [5.3a,](#page-36-0) or using standard models of the particle environment other than AE-8, it shall be demonstrated that the achieved RDM includes the model uncertainties.
	- NOTE The model uncertainties are reported in the radiation environment specification as specified in ECSS-E-ST-10-04, clause 9.3.
- c. Where the radiation environment models are worst-case in the radiation environment specification, as specified in ECSS-E-ST-10-09 clause 9, no additional margin shall be applied.
- d. Where models are of a probabilistic nature, the level of risk to be used shall be agreed between customer and supplier and reported alongside the achieved RDM.
	- NOTE Examples of models of a probabilistic nature are statistical solar proton models. Examples of an acceptable level of risk are worst case and specific percentiles.
- e. Where models are of a probabilistic nature further margin need not be applied if it is demonstrated that the intrinsic uncertainties in the instrument data underlying the model are included in the model's probabilistic formulation.
	- NOTE Any margin associated with the environment prediction is strongly dependent on the available knowledge and is used to mitigate against the uncertainties in the environment. Experience with certain types of Earth orbit is extensive, giving rise to smaller margins, but uncertainties for others, and for example other planets, necessitate careful consideration of uncertainties.



# **5.4 Deposited dose calculations**

- a. One of the three following methods shall be used to evaluate the deposited dose:
	- abstract simple shielding such as planar or spherical shell geometry, as specified in clause [6.2.2.1;](#page-48-0)
	- 3-D sector shielding, as specified in clause [6.2.3;](#page-50-0)
	- 3-D physics-based Monte-Carlo analysis, as specified in clause [6.2.4.](#page-51-0)

NOTE They are ordered in increasing accuracy and rigour.

- b. In establishing the shielding contribution to a component's RDM, and when the simulation models less than 70% of the equipment mass, then the model is conservative, and additional margin shall not be applied to doses computed in geometries with the 3-D sector shielding method specified in claus[e 6.2.3.](#page-50-0)
	- NOTE 1 This is true when approximate geometry models are used which are demonstrably conservative (e.g. lacking modelling of some units, harness, mass and fuel).
	- NOTE 2 3-D sector analysis methods (slant/solid or Norm/shell) for electron dose calculations are not always worst case. In one study a corrective factor of about 2 was needed for the Slant/Solid method and 3.4 for the Norm/Shell.
- c. In establishing the shielding contribution to a component's RDM, and when 3-D physics-based Monte-Carlo analysis specified in clause [6.2.4](#page-51-0) is used for electron-bremsstrahlung dominated environments, it shall be demonstrated that the achieved RDM includes the uncertainties (including the level of conservatism in the shielding and the systematic and statistical errors in the calculation).
	- NOTE 1 Examples of electron-bremsstrahlung dominated environments are geostationary and MEO orbits.
	- NOTE 2 When 3-D Monte-Carlo analysis is used for ionnucleon shielding in heavily shielded situations (e.g. ISS and other manned missions) greater margins are used.

# **5.5 Radiation effect behaviour**

### **5.5.1 Uncertainties associated with EEE component radiation susceptibility data**

a. It shall be demonstrated that the achieved RDM includes the uncertainties that arise in component susceptibility data from the

<span id="page-38-0"></span>

radiation hardness assurance programme specified in ECSS-Q-ST-60 for Class 1, 2 and 3 components, including:

- 1. uncertainties in the results from irradiation: the beam characterization and dosimetry, and the subsequent statistical errors in the measured or derived results such as SEE crosssections;
- 2. differences between the test circuit and the application circuit, such as bias conditions, opportunities for annealing or ELDRS;
- 3. differences in the radiation susceptibility of different components within the same batch, or within the collection of batches selected for testing;
- 4. differences between part batches or collection of batches, where errors arise from relating the results from component irradiations to devices employed in the final application;
- 5. the possible effects of packaging on low-energy proton beams (<30 MeV);
	- NOTE The reason is that this packaging can affect the penetration and energy (LET) of the particles.
- 6. the stated accuracy of the facility together with the uncertainties in requirement [5.5.1a.1,](#page-38-0) taking into account position, attenuation;
	- NOTE 1 In the absence of contemporaneous beam characterisation, quoted particle accelerator characteristics are assumed to be no better than ±30 % accurate in beam intensity.
	- NOTE 2 For γ-ray sources such as  ${}^{60}Co$ , uncertainties in the total ionising dose delivered are typically better than ±10 %.
- 7. the variations in performance within a device population, be determined by employing one or more of the following and in accordance with the radiation hardness assurance programme defined according to ECSS-Q-ST-60 for Class 1, 2 and 3 components:
	- (a) statistical techniques applied to test data;
	- (b) data from heritage information concerning the part;
	- (c) data from previous worst case analyses.
		- NOTE Such techniques are defined in the clauses of ECSS-Q-ST-60 relevant to "Radiation Hardness".

### **5.5.2 Component dose effects**

- a. In assessment of a part's total dose behaviour (ionizing and nonionizing), the achieved RDM shall include the following items as part of the radiation hardness assurance process:
	- 1. test conditions leading to worst-case,



- 2. lot-to-lot variability,
- 3. intra-lot variability,
- 4. worst-case analysis as specified in ECSS-Q-ST-30,
- 5. consistency of test results with respect to previous testing.
	- NOTE The main margin in radiation dose assessment is provided through the radiation hardness assurance plan. As specified in ECSS-Q-ST-60, a radiation hardness assurance plan is prepared, agreed and reviewed at all mission phases.
- b. If a device is sensitive to TNID, then this shall be included in the establishment of the achieved RDM.

### **5.5.3 Single event effects**

#### **5.5.3.1 General single event**

- a. It shall be demonstrated that the equipment reliability requirements include the potential for large uncertainties in predicting SEE.
	- NOTE 1 For a rationale, see clause [5.1.3.](#page-34-0)
	- NOTE 2 It is common practice in SEE evaluation to use worst-case environmental assumptions and perform worst-case analysis of system impacts. As indicated in clause [5.2,](#page-34-1) when such worstcase analysis is performed, additional margins are not applied.
	- NOTE 3 Prediction errors of a factor 10 are possible in some circumstances.
- b. Where the SEE calculation is based on an environment prediction which includes the confidence level for the environment not being exceeded, the confidence level shall be reported along with the statement of the achieved RDM for SEEs.
	- NOTE Some environmental models are statistical in nature, indicating the probability of conditions being exceeded. Such models are specified in ECSS-E-ST-10-04.
- c. Margin shall be guaranteed through application of the hardness assurance programme as specified in ECSS-Q-ST-60.

#### **5.5.3.2 Destructive single event**

a. In the case of destructive single event effect, the acceptable probability of component failure by the SEE mechanism, and the calculated probability of failure used to determine the achieved RDM, shall relate to performance of the component for the environment over the specified period of operation, rather than simply the worst-case environment condition.



- NOTE 1 Worst-case conditions can correspond or not to actual operating environment.
- NOTE 2 In many cases it can be demonstrated that environment contributions from non-worstcase conditions are negligible compared with the worst-case environment.
- b. RDM analysis need not be performed for component destructive SEE if:
	- 1. the threshold energy (for protons or neutrons) or threshold LET (for ions) for destructive SEE is greater than that identified as the immunity threshold in the radiation hardness assurance programme, or
	- 2. the electrical operational conditions for a component have been derated to levels where the device is shown by testing not to suffer that particular SEE mechanism.

### **5.5.4 Radiation-induced sensor background**

- a. The radiation metric used in the radiation design margin for sensor background calculations shall be agreed with the customer.
- b. The radiation metric used in the achieved RDM shall be chosen as representative of the sensor bandwidth critical to the mission objectives.
	- NOTE 1 It is highly dependent upon the sensor design and application. It can be provided by the customer in the equipment requirements.
	- NOTE 2 As with single event effects, the MRDM required can be dependent upon the phase of the mission, and local environment.
- c. Where the background has been simulated, a comparison between simulations and irradiation results for the sensor (or a representation of the sensor) shall be performed in order to gauge the level of error in the modelling process.
	- NOTE The uncertainties associated with the calculation of the background are very much dependent upon the sensor or instrument design and method for calculating detector background, including, where appropriate, the use of experimental data.

### **5.5.5 Biological effects**

- a. The protection limits and predicted exposure used to determine the achieved RDM for biological effects shall be defined in terms of one or more of the following variables:
	- 1. effective dose;
	- 2. organ equivalent dose;
	- 3. ambient dose equivalent;



- 4. directional dose equivalent;
- 5. personal dose equivalent.
	- NOTE 1 For requirements on radiation effects in biological material, see Clause [11.](#page-95-0) For background on limit exposure policies of the different Space Agencies, see ECSS-E-HB-10-12 Section 10.4.4.
	- NOTE 2 For interplanetary missions, exposure limits are not currently defined.

# **5.6 Establishment of margins at project phases**

#### **5.6.1 Mission margin requirement**

The customer specifies the minimum radiation design margins (MRDMs) depending on mission-specific constraints as specified in requirement [5.2a.](#page-34-1)

> NOTE For example, mission specific constraints: reliability, cost, and lifetime.

### <span id="page-41-0"></span>**5.6.2 Up to and including PDR**

- a. Before PDR, a worst-case assessment of unit shielding shall be made (i.e. minimum shielding thickness)
	- NOTE Before PDR an accurate geometrical model of a satellite is not generally available. As a consequence it is not possible to estimate the dose level expected at a part and so the final achieved RDM cannot be accurately assessed.
- <span id="page-41-1"></span>b. Other than the environmental margin, additional margin shall not be applied to the dose calculation at this stage.
- <span id="page-41-2"></span>c. For parts whose achieved RDM determined from the worst-case assessment specified in requirement [5.6.2a](#page-41-0) and [b](#page-41-1) falls below the MRDM specified in requirement [5.2a](#page-34-1) and where information is available, the worst case assessment shall be augmented by geometrical (sectorshielding) analysis.
- d. The shielding analysis specified in requirement [5.6.2c](#page-41-2) may be iterated, improving the geometrical fidelity at each stage so as to converge on an RDM that meets or exceeds the MRDM.
	- NOTE The shielding analysis is based on evaluation of the basic spacecraft and unit geometries, with sufficient detail of major local spacecraft elements which can improve shielding. Monte-Carlo techniques can also be attempted at this stage. The achieved RDM is evaluated considering the environmental and shielding uncertainties and possible systematic conservatism.



- e. For parts whose achieved RDM, as determined from the assessment in requirements [5.6.2a,](#page-41-0) [b](#page-41-1) and [c,](#page-41-2) falls below the MRDM specified in requiremen[t 5.2a](#page-34-2) shall be:
	- 1. declared by the supplier to have failed to meet the specification,
	- 2. reported to the customer, and
	- 3. either replaced with a part that meets the MRDM or subjected to detailed testing and analysis procedures.
		- NOTE 1 The tests and analysis procedures are specified in the clauses of ECSS-Q-ST-60 relevant to "Radiation Hardness".
		- NOTE 2 This analysis can be performed after PDR when more detail of the system geometry is available for more accurate shielding analyses.

#### **5.6.3 Between PDR and CDR**

- a. Before CDR, it shall be verified that the final radiation values, considering the uncertainties and conservatism in the environment, shielding and parts evaluation, are compatible with the specified projectspecific overall and component-specific MRDM.
	- NOTE 1 The RHA process defines the reporting expected at this stage (normally radiation analysis, including shielding).
	- NOTE 2 For components that are non-compliant with the MRDM at this stage, detailed 3-D shielding calculations can be employed to improve the fidelity of the calculation of the radiation level, or as the basis of a supplier Request for Waiver on the MRDM. The methods employed can be full and detailed sectoring or full Monte-Carlo radiation transport analysis as specified in clause [6.2.4,](#page-51-0) including a geometrical analysis of the unit, its surroundings and the spacecraft structure.

#### **5.6.4 Hardness assurance post-CDR**

- a. For radiation margin issues still open or identified after CDR, an analysis shall be performed to evaluate:
	- 1. Potential solutions.
	- 2. The functioning of the part in the context of a worst-case analysis.
	- 3. The implications at sub-system and system level.
		- NOTE 1 Problems identified or remaining close to or after CDR can be expensive to rectify.
		- NOTE 2 The pass/fail criteria in testing can be unrelated, or not closely related, to functional failure. If a



part's parameter is out of spec after testing, it can be that the parameter is not important in the equipment worst-case analysis.

# **5.6.5 Test methods**

The test method, including frequency and sample sizes, is addressed in the clauses of ECSS-Q-ST-60 relevant to "Radiation hardness". The test frequency is a direct function of the knowledge gained from previous testing and application of hardness assurance processes.

<span id="page-44-2"></span>

# **6 Radiation shielding**

# **6.1 Overview**

The assessment of the amount, type and energy of radiation arriving at any component location cannot be performed without an accurate knowledge of the external environment and also an understanding of the attenuating effect of any material between the location and the external environment. This attenuation is commonly known as shielding.

Shielding occurs in two ways; "built-in" shielding, that is the fortuitous shielding afforded by materials already included in the design, and "add-on" shielding, which is added specifically for the purposes of attenuating radiation. This clause identifies the standard approaches to be used when calculating the effects of shielding on the radiation environment experienced by a component, system or astronaut.

# <span id="page-44-1"></span><span id="page-44-0"></span>**6.2 Shielding calculation approach**

#### **6.2.1 General**

#### **6.2.1.1 Process**

- a. A first-order estimate of the influence of shielding shall be made by determining the dose or particle fluence corresponding to the most lightly shielded part of the subsystem under evaluation using the simplified approaches specified in clause [6.2.2.](#page-48-1)
- b. If the particle environment (including secondary as a result of additional shielding) behind that shielding is tolerable, further analysis need not be performed.
	- NOTE 1 Example of secondary radiation is bremsstrahlung.
	- NOTE 2 In some special circumstances (e.g. for galactic cosmic rays in high-Z materials) enhancement in radiation levels from secondary particles as a result of additional shielding can take place.



- c. In cases other than requirement [6.2.1.1b,](#page-44-0) one of the following analyses of the shielding shall be performed:
	- a sector-analysis, as specified in clause[s 6.2.2](#page-48-1) and [6.2.3,](#page-50-0) or
	- a detailed radiation transport simulation of the whole or a part of the spacecraft, as specified in claus[e 6.2.4.](#page-51-0)
	- shielding analysis as part of a simultaneous complete analysis with all sensitive locations defined, irrespective of whether problems are apparent or not.

#### **6.2.1.2 Secondary radiation**

- a. The shielding analysis specified in claus[e 6.2.1.1](#page-44-0) shall include
	- 1. the secondary radiation effects in accordance with the mission types identified in [Table 6-1.](#page-46-0)
	- 2. for specialised instrumentation agreed with the customer (such as astrophysics radiation detectors), all prompt and delayed radioactive emissions which have the potential to produce background signals.
		- NOTE This can be done either by including them in the calculations, or by demonstrating that the effect is negligible.

#### <span id="page-46-0"></span>**Table 6-1: Summary table of relevant primary and secondary radiations to be quantified by shielding model as a function of radiation effect and mission type (Part 1 of 2)**





**[Table 6-1:](#page-46-0) Summary table of relevant primary and secondary radiations to be quantified by shielding model as a function of radiation effect and mission type (Part 2 of 2)**







#### <span id="page-48-2"></span>**Table 6-2: Description of different dose-depth methods and their applications**

<span id="page-48-1"></span><span id="page-48-0"></span>precisely.

### **6.2.2 Simplified approaches**

#### **6.2.2.1 Planar and spherical geometries**

- a. For the first-order estimate of the influence of shielding, the analysis shall be performed as follows:
	- 1. Assume that the influence of material type is negligible, and the different materials can be approximated to the equivalent mass of



a single material type (such as aluminium) by a proportional change in density.

- 2. approximate the shielding geometry to one of the geometries shown in [Table 6-2,](#page-48-2) as follows:
	- (a) Approximate a configuration with two opposing lightly shielded directions to the summed effects of two finite slab shown i[n Table 6-2.](#page-48-2)
	- (b) Approximate a configuration with a light shielding in one direction with heavy rear-side shielding to a semi-infinite planar geometry.
	- (c) Approximate a configuration with uniform shielding in all directions to the solid sphere.
	- (d) Approximate a configuration with a large cavity and uniform shielding in all directions (thickness < 0,5 cavity diameter) and no significant material local to the dose point to the spherical shell geometry.
- 3. Obtain the effect-versus-depth information (the so called "dosedepth curve" and/or comparable information for particle fluence or other radiation effects parameters as a function of shielding).
- 4. Assess the minimum shielding quantity provided by the spacecraft to be used in conjunction with the effect-versus-depth.
- <span id="page-49-0"></span>5. If the shielding conditions do represent a worst-case analysis, and the component, subsystem or system performs to within the specified RDM for those shielding conditions, consider the result of the analysis as acceptable.
- 6. In case other than requirement [6.2.2.1a.5,](#page-49-0) apply the detailed shielding calculation method specified in clause [6.2.2.2](#page-49-1) or [6.2.3.](#page-50-0)
	- NOTE The first order approximation of the influence of shielding can result in an overestimation of the radiation effects, and a more detailed analysis can indeed show that the component, subsystem or system performs to within the specified RDM. This can be a worst-case estimation and so can indicate a requirement for more detailed analysis.

#### <span id="page-49-1"></span>**6.2.2.2 Simple sectoring based on solid angles**

- a. For the second-order estimate of the influence of shielding, the analysis shall be performed by using the method in clause [6.2.2.1](#page-48-0) and accounting for heterogeneous shielding by estimating the percentage of the overall solid angle  $(4\pi)$  subtended by the major elements of the configuration viewed from the shielded point.
	- NOTE The reason is that the sectoring method based on solid angles takes account of the fact that generally shielding around a point of interest is heterogeneous.

<span id="page-50-0"></span>

#### **6.2.3 Detailed sector shielding calculations**

- a. For detailed sector shielding calculations, the following shall be done:
	- 1. Assume that the influence of material type is negligible, and the different materials can be approximated to the equivalent mass of a single material type (such as aluminium) by a proportional change in density.
	- 2. Agree with the customer the specific sector shielding calculation method to use.

NOTE A summary of possible methods to use is presented in ECSS-E-HB-10-12 Section 5.

- <span id="page-50-1"></span>3. If sectoring calculation is applied, assess if one of the following cases is present:
	- (a) Performance of graded shields, dose enhancement in a semiconductor die close to materials with high-Z elements, or high-Z packaging materials, or X-ray bremsstrahlung dose in a location shielded by tantalum.
		- NOTE 1 Examples of these elements are gold, hafnium, tungsten.
		- NOTE 2 The reason is that sector shielding approach does not consider the physics involved in these phenomena. For graded shields see ECSS-E-HB-10-12 Section 5.
	- (b) The calculation includes assessment of secondary hadron levels from materials with significantly different (atomic) mass number from the original target material.
		- NOTE 1 For example: Neutrons generated by highenergy proton interactions in lead.
		- NOTE 2 This is particularly important for neutron fluxes or cosmic-ray fragments in heavily shielded manned missions or in sensitive scientific instruments.
- 4. If the assessment specified in requirement [6.2.3a.3](#page-50-1) is positive then either:
	- (a) analyse the case ensuring conservatism in the sector shielding evaluation, or
	- (b) perform the shielding calculation based on a radiation transport model in accordance with clause [6.2.4,](#page-51-0) which use the characteristics of the actual materials employed.
- 5. Use one of the following approaches for the calculation:
	- (a) Agree with the customer the method for the particular sector shielding evaluation, or
	- (b) use the "SLANT" approach for calculating the amount of material along a path, and the solid sphere geometry for



production of the dose-depth or fluence-versus-depth curve, or

- (c) use the "NORM" technique for estimating the amount of material along a path, and the spherical shell geometry for production of the dose-depth or fluence-versus-depth curve.
	- NOTE The transport model specified in clause [6.2.4](#page-51-0) considers the actual materials employed. Such calculations can be performed using, for example, a finite-difference coupled electronphoton simulation or a Monte Carlo simulation for nuclear and electron-photon interactions.
- 6. Provide to the customer a description of the calculation techniques used, including the:
	- (a) description of the sector shielding simulation method used.
	- (b) number of directional rays sampled
	- (c) dose-depth geometry type.
	- (d) results of the calculations
- 7. For protons and heavier ions, use the projected particle range for the calculation of the attenuation of the particle flux.
	- NOTE In ground based mono-energetic irradiation, particle straggling can result in an underestimation of particle effects. Extrapolated ranged can be more appropriate.
- 8. For sector shielding calculations, use a minimum of 1800 rays evenly distributed over  $4\pi$  steradians.
	- NOTE Sector shielding can be used to compute a shield distribution, rather than direct computation of radiation effects parameters. This can be a useful way of using shielding information for a number of subsequent analyses. Therefore it is important to ensure sufficient resolution of the shielding distribution (which is dependent upon the geometry and the specified precision). In such a situation, the considerations outlined above apply also for the subsequent analyses.

### <span id="page-51-0"></span>**6.2.4 Detailed 1-D, 2-D or full 3-D radiation transport calculations**

- a. For detailed radiation transport calculations, the following shall be done:
	- 1. Use for the calculation the characteristics of the actual materials used in the final structure or subsystem, or by agreement with the customer alternative materials that have similar electromagnetic (electron-photon) and nuclear cross-sections.



- NOTE Detailed radiation "transport" calculations provide a more accurate treatment of the radiation interaction processes in which the particle numbers, species, energy, and direction of propagation can change in a complex manner according to the Boltzmann transport equation. This type of calculation approach is used where aspects of the equipment or component performance and the influence of shielding cannot be adequately treated within a sector shielding analysis.
- 2. If undertaken, agree with the customer the level of physics simulation to use.
	- NOTE The objective is to ensure accurate treatment of the production of secondary particles which can affect the component, system or human, as well as the attenuation and scattering of the primary radiation (see ECSS-E-HB-10-12 Section 5.6).
- 3. Agree with the customer the number of dimensions (1-D. 2-D or 3-D) to use in the simulation.
	- NOTE The objective is to ensure that geometries are well represented and the analysis is conservative.
- 4. Use a number of primary particle simulations such that the statistical errors for the results used to infer component response are within the project's design margins for the radiation shielding model.
	- NOTE Radiation simulations employing Monte Carlo models carry both statistical and systematic errors, the latter as a result of uncertainties in the physics models and geometry approximations.

# **6.3 Geometry considerations for radiation shielding model**

#### **6.3.1 General**

- a. In implementing the different approaches in clause [6.2](#page-44-1) the radiation shielding model shall include in the calculations the following geometry elements:
	- 1. Parts packaging, as specified in claus[e 6.3.2.1.](#page-53-0)
		- NOTE Since it is the one that is the closest to the sensitive portion of the part (the die), the



influence of packaging on the radiation received by the component can be important, especially for electrons or low-energy (up to a few 10's MeV) protons.

- 2. Equipment, as specified in clause [6.3.2.2.](#page-53-1)
- 3. Spacecraft, as specified in clause [6.3.2.3.](#page-54-0)
- 4. Interfaces between spacecraft and (sub)system, as specified in clause [6.3.2.4.](#page-55-0)
	- NOTE Omission from the calculation of geometry elements normally leads to conservative calculations (higher radiation effect predictions), although some packaging and other materials near the die can enhance radiation levels in the die.

#### <span id="page-53-0"></span>**6.3.2 Geometry elements**

#### **6.3.2.1 Parts packaging**

- a. The effect of the parts packaging in the radiation shielding model shall be assessed as follows:
	- 1. Place the target point inside the package, located on top or inside the active region of the volume
		- NOTE The objective is to get the best possible estimate of the deposited dose at die level, the target point. The active region is typically a silicon chip.
	- 2. For hybrid devices containing several sensitive dies, use one target point per die.
		- NOTE The reason is that the calculated dose level can vary significantly depending on the die location.
	- 3. For situations where the total ionising dose from X-ray or  $\gamma$ -ray fields is the largest contribution, assess the influence of local high-Z materials and include it in the calculations.
		- NOTE Example of high-Z materials are gold contacts or tungsten silicide layers and vias.

#### <span id="page-53-1"></span>**6.3.2.2 Equipment**

- a. The effect of the equipment in the radiation shielding model shall be assessed as follows:
	- 1. Include in the equipment model (at least) the subsystem enclosure and printed circuit boards (PCBs), unless



- (a) worst-case calculations in which they are excluded show the component can tolerate the environment to within the RDM, and
- (b) it is demonstrated that the enclosure and PCB materials do not lead to radiation enhancement.
- 2. Either surround the target points by the actual parts package model, or use a worst case parts package.
	- NOTE Example of worst case parts package is an aluminium sphere with a thickness of 0,6 mm.
- 3. In order to get a better estimate of the radiation level, include in the model any passive element providing shielding to active elements.
	- NOTE Example of passive elements that can provide shielding are transformers, capacitors, and connectors.

#### <span id="page-54-0"></span>**6.3.2.3 Spacecraft**

- a. The effect of the spacecraft in the radiation shielding model shall be assessed as follows:
	- 1. Include in the spacecraft radiation model a representation of the structure and the boxes for equipments.
	- 2. Include in the model the material, as follows:
		- (a) Where the dominant material used in the spacecraft is aluminium, or material of similar Z, model the spacecraft as aluminium boxes of the thickness having the size of actual enclosures, containing a reduced density of aluminium to provide the equivalent mass of the actual contents.
		- (b) Otherwise, model the spacecraft with the precise material and contents as for the actual subsystem.
	- 3. Approximate the walls of the satellite to those of an aluminium box providing the equivalent areal mass.
	- 4. Assess the shielding afforded by the satellite structure for an internal subsystem either by:
		- (a) Using a worst-case calculation, and assuming normal incidence of radiation on each of the faces of the satellite box, or
		- (b) Perform a sector shielding analysis for each subsystem location to better determine the shielding distribution.
	- 5. If the spacecraft surface includes honeycomb panels, for worst case calculations, either:
		- (a) Incorporate in the radiation model only the face-panels of the honeycomb, or

<span id="page-55-1"></span><span id="page-55-0"></span>

(b) Agree with the customer the model to use to include the actual geometry and materials.

#### **6.3.2.4 Interfaces between spacecraft and (sub)system**

- a. If the internal arrangement of (sub)systems are not be available when sectoring is made of the spacecraft geometry,
	- 1. Specify the environment at (sub)system level in a way that the analysis of the (sub)system shielding and radiation effects can be made.
	- 2. If the (sub)system has a box shape, either:
		- (a) Provide the dose or fluxes to each surface, or
		- (b) Mesh the surfaces and provide the values for each mesh element.
			- NOTE While useful for engineering purposes, it is important to recognise the uncertainties in this method. It can happen that the propagation directions of the radiation and possibly the type and energy of the radiation are not retained. Nevertheless, this is generally a conservative approach.
- b. In any case other than requirement [6.3.2.4a,](#page-55-1) the actual internal arrangements of (sub)systems shall be provided by the customer and used by the supplier.
	- NOTE The satellite geometry and subsystem geometry can be exchanged between contractors and customers using available geometry exchange formats or tools.

### **6.4 Uncertainties**

The use of simplified approaches for shielding analysis geometries gives rise to uncertainties. As described above, shielding material effects, scattering and secondary radiation production are only approximately handled in "sectoring" types of calculation. Investigations of resulting uncertainties are in progress but results are not yet available.



# **7 Total ionising dose**

# <span id="page-56-0"></span>**7.1 Overview**

Ionisation induced in semiconductor materials or associated insulators, such as silicon dioxide layers, can lead to charge trapping or the formation of interface states at the semiconductor-insulator boundary, affecting component behaviour or material properties. In MOS devices, the trapped charge can lead to a shift in the gate threshold voltage, and for semiconductors in general, interface states can significantly increase device leakage currents. Materials such as polymers and glasses are also susceptible to total ionising dose (TID) effects and can suffer degradation in mechanical, electrical and optical properties.

The purpose of this clause is to give an overview of total ionising dose (TID) effects and specify the requirements for calculating the TID threat to spacecraft systems in terms of the technologies which are susceptible, and standard methods of calculation.

Radiation dose is the amount of energy per unit mass transferred by particles to a target material, in this case from ionisation and excitation. The International System unit is the gray:  $1 \text{ Gy} = 1$  J/kg, but a deprecated unit, the rad (radiation absorbed dose), is still widely used: 1 rad = 1 cGy.

Total ionising dose is included in the overall radiation assessment process.

### **7.2 General**

- a. The target material shall be reported with the TID units.
	- NOTE 1 For expressing TID effects in silicon, the units of dose commonly used are Gy(Si) or rad(Si).
	- NOTE 2 The reason of this requirement is that dose is dependent also on the target material.

# **7.3 Relevant environments**

- a. Total ionising dose effects shall be analysed for spacecraft and planetarymission systems to be operated within any of the following radiation environments:
	- 1. Trapped proton and electron belts
		- NOTE For example, terrestrial and other planetary belts, such as Jovian.



- 2. Solar protons
- 3. Secondary particles, except secondary neutrons
	- NOTE This includes bremsstrahlung from electrons, and protons generated in atmospheric showers in the planetary environment or within large spacecraft or planetary-lander structure.
- 4. Local sources of radiation.
	- NOTE For example, in close proximity to radioactive or nuclear-energy sources, e.g. RTGs generating γ radiation.

### **7.4 Technologies sensitive to total ionising dose**

- a. If one of the technologies identified in [Table 7-1](#page-58-0) is used in spacecraft and planetary-mission systems, the potential TID level and effects shall be analysed.
	- NOTE 1 Technologies in [Table 7-1](#page-58-0) are susceptible to TID. This is not exhaustive and other parameters can be important and result from worst-case analysis.
	- NOTE 2 As specified in Clauses [8,](#page-62-0) [9](#page-69-0) and [10,](#page-83-0) calculation of cumulative damage due to non-ionising energy loss and single event effects and detector background is also mandatory for many of these components, such as those based on bipolar junction transistors or optoelectronics.



<span id="page-58-0"></span>

### **Table 7-1: Technologies susceptible to total ionising dose effects**



# **7.5 Radiation damage assessment**

### **7.5.1 Calculation of radiation damage parameters**

- a. The radiation damage assessment shall use the total ionising dose due to charged particles and X-rays, calculated as specified in clause [7.5.2.](#page-59-0)
- b. The influence of shielding in attenuating the primary particle environment and modification to its spectrum at the component location shall be analysed, including the effects of the component packaging, as specified in Clause [6.](#page-44-2)
- c. The influence of secondary particles on TID shall be analysed.
	- NOTE The analysis can conclude that their contribution is negligible compared with the residual primary radiation components. This secondary radiation is typically electroninduced bremsstrahlung but in some circumstances secondary protons, electrons and neutrons can also have an important contribution.
- d. For items in unshielded or lightly shielded locations, the energy spectrum at low energy shall be as specified in the radiation environment specification from ECSS-E-ST-10-04 clause 9.3.

### <span id="page-59-0"></span>**7.5.2 Calculation of the ionizing dose**

- a. The calculation of the ionising dose in the target shall use the particle fluxes at the surface of the TID-sensitive elements of the component or material.
	- NOTE Methods for the related shielding calculation are specified in clause [6.2.](#page-44-1)
- b. At a point or in a finite volume, the dose shall be calculated as follows:
	- 1. Calculate particle ionization energy as follows:
		- (a) Calculate charged particle ionisation restricted stopping power (or LET) in the material, or in the case of photons, mass energy absorption coefficients, or
		- (b) Calculate particle ionisation energy deposition in a volume where the radiation field suffers negligible change (either by attenuation or multiple scattering, traversing the volume) or extended volumes.
			- NOTE Monte-Carlo methods can be used for this purpose.
	- 2. Use tabulations of dose versus flux and shielding information.
		- NOTE This is the case of SHIELDOSE and SHIELDOSE-2, based on Monte-Carlo calculation and energy loss functions.



- c. Analyse dose enhancement effects due to changes in material composition in the vicinity of, or within a target, as a result of using high-Z materials.
	- NOTE For more details on dose enhancement phenomena, see ECSS-E-HB-10-12, section 5.f.

# **7.6 Experimental data used to predict component degradation**

- a. The use of component test data used in conjunction with total ionising dose results to predict degradation shall be agreed with the customer.
	- NOTE The objective is that these data are produced from irradiations performed using particles with sufficient energies to traverse the sensitive part of the device and doses defined through application of the methods defined in the clauses of ECSS-Q-ST-60 relevant to "Radiation hardness". It is important that the testing conditions are appropriate to the final operating conditions, for example:
		- That the electrical and environmental test conditions (e.g. voltage bias, temperature) are equivalent to the expected operating environment for the device, or be such as to give rise to more severe TID effects.
		- That the time period over which the radiation dose is delivered is considered when comparing the dose received in the operational environment and under test conditions. Some bipolar devices (e.g. bipolar linear integrated circuits) exhibit greater radiation sensitivity when exposed to ionising radiation at lower TID rates, whilst others such as MOS-based devices suffer lower radiation effects if exposure takes place over a longer time.
		- That the irradiation by different radiation types is equivalent. For example, dose enhancement effects can be experienced in the shielded bremsstrahlung field in electron-rich orbits due to presence of high-Z materials close to sensitive volumes, whereas these are not represented in a proton or 60Co irradiation.



# **7.7 Experimental data used to predict material degradation**

- a. The dose deposition from the source used to assess material degradation shall be calculated through application of the methods specified in clause [7.5.2.](#page-59-0)
	- NOTE Refer to ECSS-Q-ST-70-06 and ISO/DIS 15856 for further details.

# **7.8 Uncertainties**

Refer to Clause [5.](#page-33-0)

NOTE Further discussion of uncertainties can also be found in ECSS-E-HB-10-12 Sections 4 and 5.8.



# **8 Displacement damage**

# <span id="page-62-0"></span>**8.1 Overview**

This chapter explains the displacement damage (DD) effect, identifies technologies and components susceptible to DD, and specifies the requirements for calculating the DD threat to spacecraft systems, and standard methods of calculation.

Displacement damage (also referred to as non-ionising dose damage) is a cumulative damage process induced by energetic particles and which affect components such as opto-electronics, bipolar devices, and solar cells. The damage mechanism is as a result of collisions with atoms to displace them from lattice positions creating interstitials and vacancies. These interstitials and vacancies are mobile and can cluster together or react with impurities in the lattice structure creating stable defect centres. The overall effect of displacement damage (DD) is a change in the minority carrier lifetimes of semiconductors, and increased light absorption and colouration in crystalline optical materials.

Displacement damage is sometimes quantified in terms of component degradation as a function of particle fluence for a specific particle spectrum (with units, for example, or protons/cm2 or electrons/cm2). However, since the level of degradation varies with spectrum shape as well as intensity, such a definition has limited applications, and for general applications, in this Standard DD is expressed as specified in clause [8.2.](#page-62-1)

Total non-ionising dose is included in the overall radiation assessment.

# <span id="page-62-1"></span>**8.2 Displacement damage expression**

- a. The displacement damage shall be expressed either by:
	- Displacement damage equivalent particle fluence (DDEF) for mono-energetic spectra,
		- NOTE For example, damage induced as a function of fluence from 10 MeV protons, 1 MeV neutrons or 1 MeV electrons, identified by DDEF(particle, energy, material).
	- The non-ionising energy loss (NIEL) dose or (total) non-ionising dose ((T)NID), i.e. the energy deposition in a material per unit mass by radiation through displacements.



- NOTE 1 This is distinctly different to TID for which energy is deposited as ionisation and excitation.
- NOTE 2 Units of TNID are Gy(material) or rad(material), but for space radiation effects analysis, MeV/g is more commonly used to avoid confusion with TID-related quantities.

### **8.3 Relevant environments**

- a. Displacement damage effects shall be analysed for spacecraft and planetary mission systems to be operated within any of the following radiation environments:
	- 1. Trapped proton belts

NOTE For example, terrestrial and other planetary belts, such as Jovian.

- 2. Solar protons
- 3. Secondary protons and neutrons
	- NOTE They can be generated in atmospheric showers in the planetary environment or within the spacecraft or planetary-lander structure.
- 4. In close proximity to radioactive or nuclear-energy sources

NOTE For example, RTGs generating thermal or fission-spectrum neutrons.

- 5. Trapped electrons (when considering solar cell degradations and opto-electronic devices).
- b. Displacement damage from cosmic ray primary and secondary radiation shall be treated as agreed with the customer.
	- NOTE It is normally neglected for effects in microelectronics, but it can be important for special or novel scientific instruments and sensors. While NIEL increases with atomic number of the projectile, the reducing fluence of ions with Z means that cosmic-ray heavy ion contribution to TNID is not normally significant.

### **8.4 Technologies susceptible to displacement damage**

- a. If one of the technologies identified in [Table 8-1](#page-66-0) is used in spacecraft and planetary-mission systems, the potential TNID level and effects shall be analysed.
	- NOTE As specified in Clauses [7,](#page-56-0) [9](#page-69-0) and [10,](#page-83-0) calculation of total ionising dose effects and single event effects or detector background, including



potential synergistic effects of DD and other effects, is also a requirement for many of these components.

### **8.5 Radiation damage assessment**

### **8.5.1 Calculation of radiation damage parameters**

- a. The radiation damage assessment shall use either the DDEF of monoenergetic protons, electrons, or neutrons calculated as specified in clause [8.5.2.1,](#page-64-0) or the TNID, calculated as specified in clause [8.5.2.2.](#page-65-0)
- b. The influence of shielding in attenuating the primary particle environment and modifying its spectrum shall be analysed.
	- NOTE Methods for the related shielding calculation are specified in clause [6.2.](#page-44-1)
- c. The influence of secondary protons, electrons and neutrons on displacement damage shall be analysed.
	- NOTE In many cases the analysis can conclude that their contribution is negligible, but in some circumstances secondary protons, electrons and neutrons can have an important contribution.

### <span id="page-64-0"></span>**8.5.2 Calculation of the DD dose**

#### **8.5.2.1 Calculation of the DDEF**

- a. DDEF shall be calculated from the environmental proton, electron or neutron spectra and the conversion factors for the device type being assessed as follows:
	- 1. Divide the TNID from clause [8.5.2.2](#page-65-0) by the NIEL value for the considered material and particle species at the energy required.
		- NOTE The reason is that the level of displacement damage observed per unit fluence is highly dependent upon the material and the particle energy and species.
	- 2. Calculate the DDEF as a function of equivalent shielding thickness and for each particle (trapped protons and electrons, and solar protons) spectrum estimated for a specified mission.
	- 3. Predict the decrease in performance of a component from tests performed on the component at those mono-energetic energies.
		- NOTE Typically 10 MeV proton fluences or 1 MeV electron equivalent fluence is used, these are defined based on NIEL values for the considered material and radiation environment



specification. If no valid NIEL values are available in the open literature, they are determined following methodologies presented in [\[4\]](#page-103-0) or [\[5\].](#page-103-1)

b. The decrease in the component performance shall be calculated from experimental performance test data collected on the component at these mono-energetic energies.

#### <span id="page-65-0"></span>**8.5.2.2 Calculation of the TNID**

- a. TNID shall be calculated by one of the following procedures:
	- 1. If the NIEL as a function of energy, particle type and target material is known, calculate the TNID through the integration over energy of the NIEL function (multiplied by fluence) for each particle species on the target material.
	- 2. Otherwise, calculate the NIEL as a function of energy for the material and particle type following a methodology agreed with the customer and calculate the TNID through the integration over energy of the NIEL function (multiplied by fluence) for each particle species on the target material.
		- NOTE Methodologies described by Jun *et al* or Messenger *et al* [\[4\]](#page-103-0) [\[5\]](#page-103-1) can be used for this purpose.
- b. Conversion from TNID to component parameter degradation shall be obtained by testing the component to different TNID levels.
- c. The same NIEL function shall be used in converting the test particle fluence to the test TNID in requirements [8.5.2.2a](#page-65-0) and [8.5.2.2b,](#page-65-0) and the calculation and approach shall be specified.



<span id="page-66-0"></span>

#### **Table 8-1: Summary of displacement damage effects observed in components as a function of component technology**





### **Table 8-2: Definition of displacement damage effects**



# **8.6 Prediction of component degradation**

- a. Prediction of component degradation as a function of NIEL shall be performed by one of the following approaches:
	- 1. Calculate the degradation from the total TNID damage predicted considering both elastic and inelastic processes, or
	- 2. By using experimental degradation data for high energy protons, accepted by the customer.
		- NOTE 1 It is important that the testing conditions are appropriate to the final operating conditions, for example:
			- That the component test data used in conjunction with radiation damage parameters to predict degradation are based on tests performed with particle species and energy that are representative of the environment, taking account of the appropriate NIEL conversion data.
			- That contamination of the TNID effects data by TID effects are be minimised and taken into account.
			- That the particle energies for the tests are sufficient to allow particles to traverse the sensitive part of the device.
			- For solar cells, that normal incidence data are converted to represent the expected inflight distribution (normally assumed isotropic – see ECSS-E-ST-10-04) and cover glass shielding effects.
			- That mono-energetic particle tests are permitted provided there is a consistent oneto-one correspondence between the device degradation and TNID, or if the particle energy chosen for testing leads to worst-case degradation of the device.
		- NOTE 2 For guidelines on predicting component degradation as a function of NIEL, see ECSS-E-HB-10-12 Section 7.3.

# **8.7 Uncertainties**

Refer to Clause [5.](#page-33-0)

NOTE Further discussion of uncertainties can also be found in ECSS-E-HB-10-12, Sections 4, 5.8 and 7.



# **9 Single event effects**

# <span id="page-69-0"></span>**9.1 Overview**

This Clause provides an explanation of single event effects, identifies technologies and components susceptible to the SEEs, and specifies the methods to be used to calculate single event rates for spacecraft systems.

Single event effects are a collection of phenomena whereby microelectronics can be disrupted or permanently damaged by single incident particles (as opposed to effects like total ionising dose where cumulative damage occurs from many particles). Protons and heavier ions, and neutrons can induce such effects: in the case of heavy ions, this occurs by direct ionisation of sensitive regions of the semiconductor, and for protons and neutrons, their nuclear interactions within or very near to the active semiconductor can produce localised charge generation.

SEE phenomena can be divided into two sub-groups:

- destructive effects, where high-current conditions are induced which have the potential to destroy the device. SEE examples include single event latch-up (SEL), single event gate rupture (SEGR), single event burn-out (SEB), and single event snap-back (SESB) (see ECSS-E-HB-10-12 Section 8.6).
- non-destructive effects, in which data are corrupted or the device is placed in a different operational state (*e.g.* a diagnostic mode) or power cycling is employed to return the state of the device to its normal condition. Examples of such effects include single event upset (SEU), multiple-bit upset (MBU), multiple-cell upset (MCU), single-word multiple-bit upsets (SMU), single event functional interrupt (SEFI), single event hard error (SEHE), single event disturb (SED), and single event transient (SET) (see ECSS-E-HB-10-12 Section 8.7).
	- NOTE Here, the term multiple-cell upset (MCU) refer to events in which several memory cells are corrupted, whether they form part of the same word (as in SMU) or not.

Radiation susceptibility of a device is expressed as a cross-sectional area, usually in units of cm<sup>2</sup>/device or cm<sup>2</sup>/bit (the latter being used for single event upset analysis). The cross-section is a function of incident particle species and energy. However, for ions heavier than protons, the cross-section can be expressed as a function of linear energy transfer (LET), which is the energy deposition per unit pathlength of the ion, often expressed in units of MeV⋅cm2/g or MeV⋅cm2/mg.



# <span id="page-70-0"></span>**9.2 Relevant environments**

- a. Single event effects shall be analysed for spacecraft and planetarymission systems to be operated within any of the following radiation environments:
	- 1. trapped proton belts (terrestrial and other planetary belts, such as Jovian);
	- 2. solar protons and heavier ions;
	- 3. galactic cosmic-ray protons and heavier ions;
- b. The mission environmental specifications shall define all the relevant environments to be analysed.
	- NOTE In some special circumstances, the following environments can also make an important contribution to SEE:
		- secondary protons and neutrons, which are generated in atmospheric showers in the planetary environment or within massive spacecraft or planetary-lander structures.
		- neutron environment in close proximity to radioactive or nuclear-energy sources, e.g. RTGs generating thermal or fissionspectrum neutrons.

# **9.3 Technologies susceptible to single event effects**

- a. If one of the technologies identified in [Table 9-1](#page-71-0) is used in spacecraft and planetary-mission systems, the SEE probability and effects shall be analysed.
	- NOTE 1 As specified in Clauses [7,](#page-56-0) [8](#page-62-0) and [10,](#page-83-0) the susceptibility of many of these components is also analysed for other radiation effects (such as total ionising dose and displacement damage).
	- NOTE 2 As technologies evolve and new phenomena are identified, it can be the case that this table does not fully represent the technologies and effects.
	- NOTE 3 Derating is employed in the RHA programme to ensure that the device operates in a manner so as to be insensitive to SEE effects.





# <span id="page-71-0"></span>**Table 9-1: Possible single event effects as a function of component technology and**

# **9.4 Radiation damage assessment**

### **9.4.1 Prediction of radiation damage parameters**

#### **9.4.1.1 General**

- a. When predicting component SEE rates, the following shall be assessed:
	- 1. The probability of SEE occurrence for the environments as specified in clause [9.2,](#page-70-0) using the methods specified in clause [9.4.1.2](#page-72-0) to [9.4.1.8.](#page-76-0)
		- NOTE 1 More information on this method is available in ECSS-E-HB-10-12 Section 8.2.


- NOTE 2 Total ionising dose induced in semiconductors can increase sensitivity to single event effects. Therefore, potential SEE/TID synergy can be important in special cases, both in estimating single event rate for the operating environment, as well as assessing the suitability of data collected from proton and ion beam irradiations.
- NOTE 3 In some special cases, single event effect rates have been shown to vary significantly depending upon the angle of incidence of the incident particle, even for protons and neutrons.
- 2. The influence of shielding in attenuating the primary particle environment and modification to its spectrum, as specified in Clause [6.](#page-44-0)
	- NOTE The effects of the component packaging (as described in Claus[e 6.3\)](#page-52-0) can be considered.

#### <span id="page-72-0"></span>**9.4.1.2 Heavy ion-induced SEU, MCU (including SMU), and SEFI**

- a. The probability of single event transients, upsets, functional interrupts and multiple-cell upsets due to ions heavier than protons shall be determined as follows:
	- 1. If the variation of the ion cross-section with LET is known, by using the Integrated RPP (IRPP) approach described in requirements [9.5.2a.1](#page-78-0) an[d 9.5.2a.3.](#page-80-0)
	- 2. Otherwise, using either of the following RPP methods:
		- (a) The incident particle differential LET spectrum, integrated over the integral chord-length distribution in the sensitive volume for which the energy deposition is above that corresponding to the experimentally-determined LET threshold of the device, and using the formulation of "Bradford" specified in requirement  $9.5.2a.2(b)$ .
		- (b) The differential chord-length distribution integrated over the incident particle integral LET spectrum, for which the LET corresponds to energy deposition above the experimentally-determined threshold of the device, and using the formulation of: "Bradford" or of "Pickel" or of "Blandford and Adams" specified in requirement  $9.5.2a.2(b)$ .
- b. SEFI analysis shall
	- 1. assess the range of internal operating modes employed in complex digital devices used by the intended application, and
	- 2. use only test data which cover these modes.

<span id="page-73-1"></span>

#### **9.4.1.3 Proton- and neutron-induced SEU, MCU (including SMU), and SEFI**

- a. The probability of single event transients, upsets, functional interrupts and multiple-cell upsets due to protons or neutrons shall be determined as follows:
	- 1. If the variation of the cross-section with particle energy is known,
		- (a) Calculate the probability by integration of the incident differential proton or neutron spectrum over the experimentally determined cross-section of the device as specified in clause [9.5.3.](#page-80-1)
		- (b) If experimental data from ion beam irradiations demonstrate that the threshold for SEU, MCU or SEFI for ions is less than 15 MeV⋅cm2/mg, agree with the customer if the device can be considered immune to proton and neutron SEE effects.
			- NOTE The immunity to proton/neutron SEE for devices with an LET threshold for ion SEE >15 MeV cm2/mg is an approximation. This assumption becomes inaccurate with the increasing inclusion of high-Z materials that give rise to nuclear reactions. The radiation hardness assurance programme resulting from application of ECSS-Q-ST-60 specifies the approach to be taken in special cases.
	- 2. Otherwise, perform the following:
		- (a) determine the SEE rate from calculation of the energydeposition spectrum from proton-nuclear or neutronnuclear interactions within the representation of the sensitive volume, and
		- (b) integrate this spectrum with cross-section data from ionbeam irradiations as specified in clause [9.5.3,](#page-80-1) and
		- (c) analyse potential problems arising from use of the device, along with appropriate margins.
			- NOTE The reason is that this method is not as accurate as direct calculation based on proton data.
- b. SEFI analysis shall
	- 1. assess the range of internal operating modes employed in complex digital devices used by the intended application, and
	- 2. use only test data which cover these modes.

#### **9.4.1.4 Heavy ion-induced SEL and SESB**

- <span id="page-73-0"></span>a. For SEL and SESB experimental data shall be used to determine the LET threshold for susceptibility to SEL or SESB.
- b. Where experimental data indicate that the normal incidence LET threshold for susceptibility to single event latch-up or single event snapback for ions is ≥60 MeV⋅cm<sup>2</sup>/mg, it shall be assumed that the device



has negligible probability of SEL or SESB respectively to heavy ions, when subjected to the electrical and temperature conditions under which the device is operated in the test and intended application, as specified in clause [9.4.2.](#page-76-0)

- <span id="page-74-0"></span>c. For devices with lower thresholds than those specified in requirement [9.4.1.4a,](#page-73-0) one of the following two methods shall be used:
	- 1. Determine the probabilities for SEL and SESB due to heavy ions from the integration of the incident differential ion LET spectrum over the experimentally-determined cross-section of the device, as specified in clause [9.5.2.](#page-78-2)
	- 2. worst case analysis based on experimental data.
		- NOTE Alternative testing methods (laser or proton irradiation), combined with a cross-section equivalent to the device surface can be used with worst case analysis.
- d. If a worst-case analysis is performed in accordance with requirement [9.4.1.4c.2,](#page-74-0) and the probability is unacceptable to the customer, the crosssection shall be determined experimentally.

#### <span id="page-74-1"></span>**9.4.1.5 Proton- and neutron-induced SEL and SESB**

- a. For SEL and SESB experimental data shall be used to determine the LET threshold for susceptibility to SEL or SESB.
- b. Where experimental data indicate that the LET threshold for susceptibility to single event latch-up or single event snapback for ions is ≥15 MeV⋅cm2/mg, or proton or neutron data indicate that the energy threshold for proton/neutron SEE is  $\geq$ 150 MeV, it shall be assumed that the device has negligible probability of SEL or SESB respectively for protons and neutrons. When subjected to the electrical and temperature conditions under which the device is operated in the test and intended application, as specified in clause [9.4.2.](#page-76-0)
	- NOTE 1 It is an assumption that devices with an LET threshold for ions >15 MeV cm2/mg are immune to SEL and SESB. This assumption becomes inaccurate with the increasing inclusion of high-Z materials that give rise to nuclear reactions. The radiation hardness assurance programme resulting from application of ECSS-Q-ST-60 specifies the approach to be taken in special cases.
	- NOTE 2 SEL cross sections can increase by a factor of four between 100 and 200 MeV and by a further factor of 1,5 to 500 MeV.
- c. For devices with lower thresholds that the ones specified in requirement [9.4.1.5a,](#page-74-1) the probabilities for SEL and SESB due to protons or neutrons shall be determined by one of the following methods:



- 1. by integration of the incident differential proton or neutron spectrum over the experimentally determined cross-section of the device, as specified in clause [9.5.3.](#page-80-1)
- 2. by worst case analysis.
	- NOTE Alternative testing methods (laser irradiation), combined with a cross-section equivalent to the device surface can be used with worst case analyses.

#### <span id="page-75-0"></span>**9.4.1.6 Heavy ion-, proton- and neutron-induced SEGR, SEDR and SEB**

- a. For single event gate/dielectric rupture and single event burnout, experimental data shall be used to determine the electrical operational conditions of the device under which neither SEGR nor SEB occurs
	- NOTE ECSS-E-HB-10-12 Section 8.5.8 describes derating and mitigation techniques for defining electrical operational conditions.
- b. Where experimental data show that the threshold for single event gate/dielectric rupture or single event burnout in a device for ions is ≥60 MeV⋅cm2/mg, it shall be assumed that the device has negligible probability of SEGR, SEDR or SEB respectively for operation in heavyion, proton and neutron fields, when it is subjected to the electrical and temperature conditions under which the device is operated in the test and intended application in accordance with clause [9.4.2.](#page-76-0)
- c. Where experimental data show that the threshold for SEGR, SEDR or SEB for ions is ≥15 MeV⋅cm2/mg, or proton or neutron data indicate that the energy threshold for proton/neutron SEGR, SEDR or SEB is ≥ 150 MeV, it shall be assumed that the device has negligible probability of SEGR, SEDR or SEB respectively when operated in either a proton or neutron field when it is subjected to the operating conditions or the test and application.
- d. In the case specified in requirement [9.4.1.6c,](#page-75-0) the device's susceptibility to heavy-ion induced SEGR, SEDR and SEB shall be analysed.

#### **9.4.1.7 Heavy ion-, proton- and neutron-induced SET and SED**

- <span id="page-75-1"></span>a. If SET is mitigated by circuit design, the effects of spurious pulses shall be minimized as follows:
	- 1. Test the equipment performance under different filter conditions for SET and SED effects by propagating a perturbation signal in the final electrical design of the hardware itself to study its influence at the system level.
		- NOTE This approach is used when there is sufficient access to inject test pulses to the range of circuit nodes, or using a circuit simulation mode.
	- 2. Use a circuit simulation model, and verify the accuracy of the different components in the circuit model for propagating large



amplitude signals, up to the maximum amplitude expected from the SET/SED.

- NOTE Typical applied amplitudes and signal durations are provided in ECSS-E-HB-10-12 Section 8.5.9 (Table 9) as a function of semiconductor family type. Note, however, that these are not the only devices to be tested for SET/SED.
- b. In case other than requirement [9.4.1.7a,](#page-75-1) the SET/SED rate shall be predicted using the same methods as for SEU, as specified in clause [9.4.1.2](#page-72-0) and [9.4.1.3,](#page-73-1) including ion or proton test.

#### **9.4.1.8 Heavy ion-, proton- and neutron-induced SEHE**

- a. The probability of single hard errors due to ions shall be determined by integration of the incident particle differential LET spectrum over the experimentally determined cross-section of the device, as a function of LET and angle of incidence.
- b. The probability of single hard errors due to protons and neutrons shall be determined by integration of the incident particle differential energy spectrum over the experimentally determined cross-section of the device, as a function of particle energy and angle of incidence.
	- NOTE ECSS-E-HB-10-12 Section 8.7.4 provides a description of SEHE and considerations that can be significant for the test procedure.

#### <span id="page-76-0"></span>**9.4.2 Experimental data and prediction of component degradation**

- a. Experimental data used to calculate single event rates shall cover a LET range (for heavy-ion induced SEEs) or energy range (for proton and neutron-induced effects) capable to ensure that:
	- 1. The lower LET or energy is less than the threshold for the onset of the single event effect.
		- NOTE 1 The lower LET or energy threshold can require extensive testing to determine. For protons it is influenced by packaging, while for neutrons it can be in the region of thermal energies if Boron-10 is present.
		- NOTE 2 Lower LET or energy threshold for the testing is specified in the radiation hardness assurance programme under ECSS-Q-ST-60.
	- 2. For heavy ions, the upper LET threshold corresponds either to:
		- (a) the maximum LET expected for the environment,
		- (b) the device LET saturation cross section,
			- NOTE Saturation is defined according to the radiation hardness assurance programme established under ECSS-Q-ST-60.
		- $\text{(c)}$  60 MeV⋅cm<sup>2</sup>/mg.



- 3. For nucleons, the maximum energy corresponds either to:
	- (a) the maximum energy for the predicted environment, or
	- (b) the device saturation cross section is in the range.
		- NOTE Saturation is defined according to the radiation hardness assurance programme established under ECSS-Q-ST-60.
	- (c) 150 MeV for all SEE phenomena.
- b. Cross section data shall be from tests where the test particle's range in the material ensures it is able to penetrate the entire sensitive volume of the device.
	- NOTE The reason is that many modern devices (including power semiconductors) have significant vertical structure and very thick epitaxial layers and sufficient range of the incident test particle is required to adequately penetrate through the entire sensitive volume of the device.
- c. The experimental data used for device conditions shall be either those expected for operational conditions, or such that the experiment provide worse SEE-susceptibility data, as follows:
	- 1. For SRAMs and DRAMs, SEU-dependent electrical conditions are voltage, clock frequency and refresh rate.
	- 2. For SEL, tests are for the maximum power and maximum temperature conditions expected for space application.
	- 3. For SEB, tests correspond to the minimum operating temperature for the application, as this corresponds to maximum SEB susceptibility of the device.
- d. For SEL, SEGR, and SEB, the potential inaccuracy of LET cross-section data obtained using obliquely incident heavy-ion beams shall be analysed and the results reported in accordance with the RHA programme established under ECSS-Q-ST-60.
	- NOTE 1 The reason is that the concepts of sensitive volume and effective LET are not strictly valid (see ECSS-E-HB-10-12 Section 8.6.1 to 8.6.3).
	- NOTE 2 SEHE cross-section can be a function of particle species and energy (i.e. not just LET) and angle of incidence (see ECSS-E-HB-10-12 Section 8.7.4).
	- NOTE 3 It is important that the ion track width of the particles used in the irradiations is sufficient to cover a significant fraction of the gate region.
	- NOTE 4 There are synergies between SEHE rates and cumulative dose (TID) as well as microdose effects.



# <span id="page-78-2"></span>**9.5 Hardness assurance**

## **9.5.1 Calculation procedure flowchart**

a. The assessment of single event effects and the suitability of the proposed hardware and mission design shall be performed as specified in [Figure 9-1.](#page-79-0)

## **9.5.2 Predictions of SEE rates for ions**

- <span id="page-78-1"></span><span id="page-78-0"></span>a. Calculation of the ion contribution to SEE rates shall be performed as follows:
	- 1. By using the LET spectra for cosmic rays and heavy ions from solar particle events given by the radiation environmental specification, obtain the cross section experimental curve giving at least LET threshold and saturation cross-section, or the Weibull parameters.
	- 2. If using RPP approach:
		- (a) Assume that the sensitive volume is a parallelepiped of the same volume as the sensitive one.
		- (b) Calculate the error rate using one of the following formulae:
			- − Bradford formula:  $=\frac{A}{4}\int_{LET_{Min}}^{LET_{Max}}\frac{d\Phi}{d(LET)}(LET)\cdot P_{CL}(>D(LET))\cdot$  $N = \frac{A}{4} \int_{LET_{Min}}^{LET_{Max}} \frac{d\Phi}{d(LET)} (LET) \cdot P_{CL} (> D(LET)) \cdot d(LET)$ with  $A = 2 \cdot (lw + lh + hw)$
			- − Pickel formula:

$$
N = \frac{A}{4} \int_{D_{Min}}^{D_{Max}} \Phi(\geq LET(D)) \cdot \frac{dP_{CL}}{dD}(D) \cdot dD
$$

− Blandford and Adams formula:

$$
N = \frac{A}{4} \frac{E_C}{\rho} \int_{LET_{Min}}^{LET_{Max}} \frac{1}{LET^2} \cdot \Phi(\gt) LET) \cdot \frac{dP_{CL}}{d(D(LET))} \cdot D(LET) \cdot d(LET)
$$

where:







<span id="page-79-0"></span>**Figure 9-1: Procedure flowchart for hardness assurance for single event effects.**

<span id="page-80-0"></span>

- 3. If using IRPP approach:
	- (a) Use the real sensitive volume for the integration.
	- (b) Calculate the error rate using the following formula:

$$
N = \frac{A}{4S} \int_{LET_{i,Min}}^{LET_{i,Mar}} \left\{ \frac{d\sigma_{ion}}{d(LET)} (LET_{i}) \int_{\frac{h}{D_{Max}}LET_{i}}^{LET_{Max}} \frac{d\Phi}{d(LET)} (LET) \cdot P_{CL} (> D(LET)) d(LET) \right\} d(LET_{i})
$$

with  $S = l \cdot w$ 

where:



#### [\[9\]](#page-103-3) and [\[10\].](#page-103-4)

#### <span id="page-80-1"></span>**9.5.3 Prediction of SEE rates of protons and neutrons**

- a. Except in the case specified in requirement [9.5.3b,](#page-80-1) the proton or neutron contribution to error rate shall be calculated as follows:
	- 1. Using the integral or differential energy spectra for protons or neutrons specified in the radiation environment specification, obtain:
		- (a) the cross-section experimental curve giving saturation, and
		- (b) two other cross section/energy points in the following ranges:
			- − For protons, in the energy range 10 MeV 200 MeV.
			- − For neutrons, from thermal energies to 200 MeV.

<span id="page-81-0"></span>

- 2. Use one of the following formulas to calculate the SEE rates:
	- o From the environment proton or neutron fluxes and SEE cross sections:

$$
N = \int_{E_{Min}}^{E_{Max}} \frac{d\Phi}{dE} (E) \cdot \sigma_{nucleon}(E) dE
$$

o By considering the dependence of the angle of incidence, but assuming not azimuth angle dependence:

$$
N = \int_{E_{Min}}^{E_{Max}} \left\{ \int_0^{\pi} \frac{\partial \Phi}{\partial E \partial \theta} (E, \theta) \cdot \sigma_{nucleon}(E, \theta) \cdot \sin \theta d\theta \right\} dE
$$

- o By simplifying the previous formula, by
	- − defining σ*max*(*E*) as the value of σ(*E*,θ) at the angle <sup>θ</sup> where the cross section maximises for that energy, and
	- − If the incident proton or neutron flux is anisotropic (and therefore cannot be approximated to an isotropic flux), approximate *d*Φ/*dE* to the angle-averaged incident flux if used in conjunction with the maximum cross section data, σ*max*(*E*).

where:

- *d*Φ*/dE* = differential proton or neutron flux spectrum as a function of energy;
- *EMin* = minimum energy of the differential energy neutron spectrum;
- *EMax* = maximum energy of the differential energy spectrum;
- *σnucleon*(*E*) = proton or neutron SEE cross section as a function of energy.
- b. If the heavy ion cross-section experimental curve exist, the proton or neutron contribution to error rate may be calculated as follows:
	- 1. Obtain the proton cross-section curve by simulation and correlation with experimental data, using a simulation tool agreed with the customer.
	- 2. Using the integral or differential energy spectra for protons or neutrons specified in the radiation environment specification, obtain two other cross section/energy points in the following ranges:
		- o For protons, in the energy range 10 MeV 200 MeV.
		- o For neutrons, from thermal energies to 200 MeV.
	- 3. Calculate the SSE rate, from ion-beam irradiations, by using the following formula:

$$
N = \frac{s_{sample}}{S} \int_{E_{Min}}^{E_{Max}} \frac{d\Phi}{dE} (E) \left\{ \int_{\varepsilon_C}^{\varepsilon_{Max}} \sigma_{ion} \left( \frac{\varepsilon}{\rho h} \right) \frac{dP}{d\varepsilon} (E, \varepsilon) d\varepsilon \right\} dE
$$



#### where:

*d*Φ*/dE,* : *EMin, EMax,* and *σnucleon*(*E*) have the same meaning as in [9.5.3a](#page-80-1)[2,](#page-81-0) and:

- $dP/d\varepsilon(E,\varepsilon)$  = differential energy deposition spectrum for protons/neutrons of energy E depositing energy e within the sensitive volume;
- <sup>e</sup>*<sup>C</sup>* = critical or threshold energy deposition for inducing SEE;
- $E_{Max}$  = maximum energy deposition defined for energy deposition spectrum;
- *σion*(*LET*) = SEE cross section for ions as a function of LET for normally incident ions;
- *h* = height of sensitive volume;
- $\rho$  = mass density of semiconductor;
- *ssample* = area of cell sampled by proton/neutron simulation to obtain energy deposition spectrum.
	- NOTE Rational and discussion on the calculation of SEE rates of protons and neutrons can be found in Section 8.5.5 to 8.5.7.



# **10 Radiation-induced sensor backgrounds**

# **10.1 Overview**

This clause provides an explanation of radiation-induced sensor backgrounds, identifies technologies and components susceptible to this phenomenon, and specifies the general approaches for assessing background rates in susceptible sensors.

Radiation-induced sensor backgrounds described in this clause refer to enhanced noise levels in detectors such as:

- IR, optical, UV, X-ray and  $\gamma$ -ray photon detectors, including those comprising single detector elements, as well as imaging arrays;
- detectors for other particle radiations;
- gravity wave detectors;

as a result of the incident radiation environment other than those components of the environment the sensor is attempting to detect. As well as signal production in these sensors from direct ionisation by charged primary particles and secondaries, delayed effects can result such as from the build-up of radioactivity in materials of the spacecraft and instrument. The effects observed (and therefore the approach for calculating background rates) are highly dependent upon the instrument design and operating conditions.

# <span id="page-83-0"></span>**10.2 Relevant environments**

- a. Radiation-induced backgrounds shall be analysed for spacecraft and planetary-missions where there is the potential for energy deposition events within the bandwidth of the sensor from the radiation environment, whether from a single event or accumulation of interaction of events.
	- NOTE Example of accumulation is from pile-up of pulses within the detector time-resolution, the cumulative effect of which exceeds the event detection threshold and results in a false event.
- b. The analysis specified in requirement [10.2a](#page-83-0) shall include all components of the environment that have the potential to affect the instrument, including secondary particles from the spacecraft structure and local planetary bodies, and man-made radiation sources
	- NOTE Example of man-made radiation sources are radioactive calibration sources, and radioisotope thermoelectric generators.





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<span id="page-85-0"></span>Table 10-1: Summary of possible radiation-induced background effects as a function of instrument technology **Table 10-1: Summary of possible radiation-induced background effects as a function of instrument technology**

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Table 10-1: Summary of possible radiation-induced background effects as a function of instrument technology **[Table 10-1:](#page-85-0) Summary of possible radiation-induced background effects as a function of instrument technology** 









# <span id="page-88-0"></span>**10.3 Instrument technologies susceptible to radiationinduced backgrounds**

- a. If one of the technologies or instruments identified in [Table 10-1](#page-85-0) is used in spacecraft or planetary-mission systems, the potential radiationinduced background effects shall analysed.
- b. The mechanisms shall be analysed by which the energetic radiation environment can deposit energy in the instrument so as to register as a sensor event.

NOTE The reason is that spacecraft scientific payloads are often unique.

- c. The analysis specified in requirement [10.3b](#page-88-0) shall include:
	- 1. Events from prompt ionisation by primary particles and all prompt secondaries

NOTE For example, X-ray fluorescence.

- 2. The potential "pile-up" of such ionising events, within the temporal-resolution of the sensor, which results in higher-thanexpected energy deposition.
- 3. Delayed ionisation effects from induced radioactivity.
	- NOTE As specified in Clauses [7,](#page-56-0) [8](#page-62-0) and [9,](#page-69-0) calculation of susceptibility to other radiation effects (total ionising dose, displacement damage, and single event effects) is also normative.

# **10.4 Radiation background assessment**

## **10.4.1 General**

- a. Radiation shielding calculations shall be performed to determine the radiation environment at the instrument after passing through the spacecraft structure.
- <span id="page-88-2"></span><span id="page-88-1"></span>b. Background effects in instruments shall be analysed using:
	- 1. calculations or simulations of the energy-deposition processes in sensitive volumes, or
	- 2. results from particle accelerator irradiations of the instrument or its sensitive components, or
	- 3. a combination of both of the requirements [10.4.1b.1](#page-88-1) and [10.4.1b.2.](#page-88-2)
- c. Where experimental results from component tests are used, or simulations based on components of the instrument, one of the following shall be performed:
	- 1. shielding calculations for the instrument, to determine the incident particle spectrum on the sensitive volume(s) of the instrument, or



- 2. an analysis demonstrating that instrument structure has a negligible perturbing effect on the radiation field.
- d. Where grazing-incidence mirrors are used, the calculation of the radiation environment at the sensitive volumes of the instrument shall include the effects of Firsov scattering and shallow angle multiple scattering of protons in the grazing-incidence mirrors.
	- NOTE See ECSS-E-HB-10-12 Section 9.4, for the reasons for including Firsov scattering in the simulation.

## **10.4.2 Prediction of effects from direct ionisation by charged particles**

- <span id="page-89-0"></span>a. The energy deposition spectrum by direct ionisation shall be calculated by one of the following methods:
	- 1. By using the formula of Clause [10.4.9.1,](#page-92-0) if both of the following conditions are met:
		- (a) the sensitive volume of the sensor is so small that the incident particle spectrum changes by less than 10% in either intensity or energy after passing through the volume;
		- (b) the pathlength distribution changes by less than 10% as a result of multiple scattering.
	- 2. By a radiation transport simulation agreed with the customer. NOTE For guidelines, see ECSS-E-HB-10-12 Section 5.7.
- b. If method specified in requirement [10.4.2a.1](#page-89-0) is used, the following shall be performed:
	- 1. An estimation of the combined effects of the maximum change in energy, intensity and pathlength on the energy deposition, and
	- 2. A demonstration that the error produced is within the accepted margins defined for the project.

#### **10.4.3 Prediction of effects from ionisation by nuclear interactions**

- a. Prediction of energy deposition spectra initiated by nuclear interaction events shall be performed by a method agreed with the customer.
	- NOTE Prediction of energy deposition spectra initiated by nuclear interactions event are usually performed using detailed radiation transport simulations (see ECSS-E-HB-10-12 Section 5.7). However, where simplifications in the interactions and energy deposition processes permit, simplified analytical solutions are applied, provided the combined effects of the approximations produce an error within the accepted margins defined for the project.

<span id="page-90-0"></span>

## **10.4.4 Prediction of effects from induced radioactive decay**

- <span id="page-90-1"></span>a. Nuclear interaction rates in the sensitive volume and surrounding materials (the radioactive decay products from which can affect the sensitive volume) shall be calculated by one of the following methods:
	- 1. By using the formula of Clause [10.4.9.2](#page-93-0) if all of the following conditions are met:
		- (a) the sensitive volume of the sensor and surrounding material producing background in the sensor are so small that the incident particle spectrum changes by less than 10% in either intensity of energy after passing through the volume;
		- (b) the pathlength distribution in the sensitive volume and surrounding material changes by less than 10% as a result of multiple scattering;
		- (c) the probability of secondary nuclear interactions is 10 times lower than the primary interaction rate.
	- 2. By a radiation transport simulation agreed with the customer.

NOTE For guidelines, see ECSS-E-HB-10-12 Section 5.7.

- b. If method specified in requirement [10.4.4a.](#page-90-0)[1](#page-90-1) is used, the following shall be performed:
	- 1. An estimation of the combined effects of the maximum change in energy, intensity and pathlength, and the influence of secondaries on the energy deposition, and
	- 2. A demonstration that the error produced is within the accepted margins defined for the project.
- c. The nuclear interaction rate shall be convolved with relevant response function spectra to radioactive decay in the sensitive volume and surrounding materials, to determine the background count rate in the sensor.

# **10.4.5 Prediction of fluorescent X-ray interactions**

a. The analysis for the prediction of fluorescent X-ray interactions shall include the induced continuum and discrete X-ray emission spectrum from materials surrounding the X-ray detector.



#### **10.4.6 Prediction of effects from induced scintillation or Cerenkov radiation in PMTs and MCPs**

- a. The method used for predicting the fluorescence or Cerenkov radiation production shall either:
	- use a radiation transport calculation that includes Cerenkov and fluorescence physics models and the instrument shielding geometry, or
	- use a simplified method capable to demonstrate that the level of error in the prediction is within the accepted margins defined for the project.
- b. The prediction shall assess the effects of:
	- 1. Direct ionisation of the cathode or dynode of a PMT by a particle, or direct ionisation of the walls of a MCP, in either case producing secondary electrons.
	- 2. Scintillation of optical components of the PMT/MCP.
	- 3. Cerenkov radiation induced in any optical components of the instrument from particles above the Cerenkov threshold.

#### **10.4.7 Prediction of radiation-induced noise in gravity-wave detectors**

- a. The method adopted for predicting the influence of the radiation environment on gravity-wave interferometric experiments shall be agreed with the customer.
	- NOTE The method adopted for predicting the influence of the radiation environment on gravity-wave interferometric experiments is normally based on a detailed radiation transport calculation, or if a simplified approach is used, the level of error in the prediction is be estimated in order to ensure that it is within the accepted margins defined for the project.
- b. The prediction shall be used to assess the noise introduced into the instrument as a result of the incident radiation:
	- 1. changing the charge of the free-floating test mass;
	- 2. acting as a source of energy to change the thermal conditions of the cryogenically cooled test mass;
	- 3. changing the critical temperature of superconducting materials.



#### **10.4.8 Use of experimental data from irradiations**

- a. Experimental data from irradiations shall be used to validate prediction techniques.
- b. If experimental data are used in place of elements of the prediction process, the parameter-space covered by experiment shall ensure that the data can be interpolated to operational environment conditions within the error limits specified by the project.
	- NOTE 1 This is especially important in assessing the response of the instrument to the local radiation environment.
	- NOTE 2 Examples of parameter space covered by the experiment are incident particle species and energy, angle of incidence, flux (to allow for effects of pulse pile-up).

## **10.4.9 Radiation background calculations**

#### <span id="page-92-0"></span>**10.4.9.1 Energy deposition spectrum from direct ionization**

- a. Under the conditions specified in requirement [10.4.2a.1,](#page-89-0) the energy deposition spectrum from direct ionization shall be calculated by using one of the following formulas:
	- 1. From direct ionization, by one of the following formulas:
		- o Detailed calculation:

$$
\frac{d\Psi}{d\varepsilon}(\varepsilon) = \frac{A}{4} \int_{E_{\text{min}}}^{E_{\text{max}}} \frac{d\Phi}{dE}(E) \cdot \frac{dP_{CL}}{dD} \left(\frac{\varepsilon}{LET(E)}\right) \cdot \frac{1}{LET(E)} dE
$$

o Approximated calculation:

$$
\frac{d\Psi}{d\varepsilon}(\varepsilon) = \frac{A}{4} \int_{E_{\text{min}}}^{E_{\text{max}}} \frac{d\Phi}{dE} (E) \cdot \frac{dP_{CL}}{dD} \left( \varepsilon \left\{ \frac{dE}{dx} (E) \right\}^{-1} \right) \left\{ \frac{dE}{dx} (E) \right\}^{-1} dE
$$

where:



spectrum.



- NOTE This expression assumes the incident particle spectrum on the detector is or can be approximated to a isotropic angular distribution. Furthermore, it is assumed that the change in the stopping power of the particle through the sensitive volume and any multiple scattering can be neglected.
- 2. For nucleon-nuclear collision-induced energy, by one of the following methods:
	- (a) If the dimensions of the detector volume are 10 times (or more) smaller than the ranges and mean-free paths of the incident particles, by using the following formula:

$$
\frac{d\Psi}{d\varepsilon}(\varepsilon) = \frac{MN_A}{W} \int_{E_{\text{min}}}^{E_{\text{max}}} \frac{d\Phi}{dE}(E) \cdot \sigma(E) \cdot \frac{dP}{d\varepsilon}(E, \varepsilon) dE
$$

where:

*d*Ψ*/d*e*(*e*), A, d*Φ*/dE(E), dPCL/dD(D), dE/dx(E), Emin,* and *Emax* have the same meaning as in Clause [10.4.9.11,](#page-92-0) and:

- *M* = mass of sensitive volume;
- *NA* = Avogadro's constant;
- *W* = atomic or molecular mass of the material making up the detector;
- $\sigma(E)$  = nuclear-interaction cross-section for the material as a whole due to incident particles of energy *E*;
- $dP/d\epsilon(E,\epsilon)$  = energy deposition rate spectrum (or response function) for incident particles of energy *E*, and energy deposition,  $\varepsilon$ .
- (b) Otherwise, by applying radiation simulation tools agreed with the customer.
	- NOTE 1 Examples of such tools are Geant4, MCNPX, and FLUKA. More examples can be found in Table 2 of ECSS-E-HB-10-12.
	- NOTE 2 For a rational and detailed discussion on energy deposition spectrum from direct ionization calculation and nucleon-nuclear interactions, see ECSS-E-HB-10-12, Section 9.2.

#### <span id="page-93-0"></span>**10.4.9.2 Nuclear interaction rates**

a. Under the conditions specified in requirement [10.4.4a.1,](#page-90-1) the nuclear interaction rates in the sensitive volume and surrounding material shall be calculated by the following formula:

$$
R_i(t) = \frac{MN_A}{W} \sum_j \int_{E_{j,\text{min}}}^{E_{j,\text{max}}} \frac{d\Phi_j}{dE}(E,t) \cdot \sigma_{j \to i}(E) dE
$$



#### where:



- *N<sub>A</sub>* = Avogadro's constant;
- *W* = atomic or molecular mass of the material making up the detector;
- *d*Φ*j/dE*(*E*,*t*) = differential incident flux spectrum expressed as a function of energy, *E* and time, *t* for particle species *j* (these are both primary and secondary particles);
- $\sigma_j$ <sub>→*i*</sub>(*E*) = nuclear-interaction cross-section for the production of nuclide i in the detector material due to incident particle species j of energy *E*;
- $E_{j,min}$  = minimum energy for the incident particle spectrum, *j*;
- $E_{j,max}$  = maximum energy of the incident particle spectrum *j*.
	- NOTE For a rational and detailed description, see ECSS-E-HB-10-12, Section 9.5.



# **11 Effects in biological material**

# **11.1 Overview**

The effects that ionising radiation produces in living matter result from energy transferred from radiation into ionisation (and excitation) of the molecules of which a cell is made. The primary effects start with physical interactions and energy transfer, after which changed molecules interact by chemical reactions and interfere with the regulatory processes within the cell.

The resulting radiobiological effects in man can be divided into two different types:

- stochastic effects, where the probability of manifestation is a function of dose rather than the magnitude of the radiobiological effect, and
- deterministic effects, where the severity of the effect depends directly on dose, with a lower threshold dose below which no response occurs.

Symptoms of radiation exposure are classified as either early or late effects, with early effects relating to symptoms that occur within 60 days of exposure, and late effects usually becoming manifest many months or years later.

This chapter summarises the radiation quantities used to define the environment relevant to radiation effects in biological materials, and specifies the requirements for quantifying radiobiological effects for space missions.

Note that the discussions in this chapter are aimed at radiation effects on man. Effects on other biological materials (*e.g.* animals or plants flown as test subjects for experiment) on unmanned or manned missions can also be assessed, based on the principles discussed here.

# <span id="page-95-0"></span>**11.2 Parameters used to measure radiation**

## **11.2.1 Basic physical parameters**

- a. The following basic parameters shall be used to measure the radiation environment:
	- 1. The absorbed dose, D
	- 2. The air kerma, K,
	- 3. The fluence, Φ, and
	- 4. The linear energy transfer, LET.

<span id="page-96-0"></span>

# **11.2.2 Protection quantities**

#### **11.2.2.1 General**

- a. The following protection quantities shall be used when relating the basic physical parameters to biological systems:
	- 1. The mean organ absorbed dose,  $D_T$
	- 2. The relative biological effectiveness, RBE
	- 3. The radiation weighting factor,  $W_R$
	- 4. The organ equivalent dose,  $H_T$
	- 5. The tissue weighting factor,  $WT<sub>r</sub>$  and
	- 6. The effective dose, E.
		- NOTE 1 Protection quantities are defined by the International Commission on Radiobiological Protection (ICRP).
		- NOTE 2 The mean organ dose, organ equivalent dose, and effective dose are not directly measurable, but are essential for assessing risk due to a radiation environment.

#### **11.2.2.2** Value of the radiation weighting factor,  $W_R$

- a. The values of the radiation weighting factor shall be as specified in [Table 11-1.](#page-97-0)
- b. Values for the radiation weighting factor of particles not specified in Table 11 shall be derived by dividing the ambient dose equivalent for the particle H\*(10) by the dose at 10 mm depth in the ICRU spher[e \[12\].](#page-103-5)
	- NOTE 1 The radiation weighting factor,  $w_R$ , accounts for the different levels of biological effects resulting from different particle types, although they can produce the same mean organ dose. For further discussion on wR see ECSS-E-HB-10-12 Section 10.2.2.
	- NOTE 2 The values in [Table 11-1](#page-97-0) are from ICRP-60 [\[11\],](#page-103-6) and are defined and maintained by the ICRP. The users are encouraged to consult the ICRP for the more recent updates.

<span id="page-97-0"></span>



#### **Table 11-1: Radiation weighting factors**

#### **11.2.2.3** Value of the tissue weighting factor,  $w_T$

- a. The values of the tissue weighting factor shall be as specified i[n Table 11-2.](#page-97-1)
	- NOTE 1 The tissue weighting factor takes into account the variability in sensitivity of different organs and tissue subject to the same equivalent dose.
	- NOTE 2 The values in [Table 11-2](#page-97-1) are from ICRP Publication 60 Table A-3 [\[11\]](#page-103-6) and are defined and maintained by the ICRP. The users are encouraged to consult the ICRP for the more recent updates.

<span id="page-97-1"></span>



<span id="page-98-1"></span>

# **11.2.3 Operational quantities**

#### **11.2.3.1 General**

- a. The following operational quantities shall be used for the assessment of radiation exposure:
	- 1. the ambient dose equivalent,  $H^*(d)$
	- 2. the directional dose equivalent,  $H'(d,\Omega)$
	- 3. the personal dose equivalent, *HP*
	- 4. the quality factor, Q
		- NOTE Operational quantities are measurable. They are defined by the International Commission on Radiation Units and Measurements (ICRU) with the aim of never underestimating the relevant protection quantities, in particular the effective dose, E, under conventional normallyoccurring exposure conditions.

#### **11.2.3.2 Value of the quality factor, Q**

a. The values of the quality factors given in Equatio[n \(3\)](#page-98-0) shall be used.

<span id="page-98-0"></span>
$$
Q(L) = \begin{cases} 1 & : L \le 10keV / \mu m \\ 0.32L - 2.2 & : 10 keV / \mu m \le L \le 100 keV / \mu m \\ 300 / \sqrt{L} & : L > 100 keV / \mu m \end{cases}
$$
 (3)

NOTE These values, related to the unrestricted LET in water, correspond to the ones given by equation below, which is established by ICRP-60 [\[11\].](#page-103-6)

# **11.3 Relevant environments**

- a. Radiobiological effects resulting from the following environments shall be analysed for all manned missions:
	- 1. trapped proton and electron belts (terrestrial and other planetary belts);
	- 2. solar protons and ions;
	- 3. cosmic ray protons and heavier nuclei;
	- 4. bremsstrahlung produced as secondaries from electrons;
	- 5. secondary protons, neutrons and other nuclear fragments which can be generated in atmospheric showers in the planetary environment or within the spacecraft or planetary-habitat structure, including the body itself.



NOTE This contribution is particularly important for cosmic-ray induced secondaries. 6. emmisions from radioactive or nuclear-energy sources on the spacecraft. NOTE For example, RTGs generating γ-ray and neutron radiation.

# <span id="page-99-1"></span><span id="page-99-0"></span>**11.4 Establishment of radiation protection limits**

- a. The project shall establish the radiation protection limits to be applied to the mission.
	- NOTE These limits are established based on the policies and standards defined by the space agency for manned space flight (see ECSS-E-HB-10-12 Section 10.4, and ECSS-E-ST-10-11). Where there is more than one space agency involved, the radiation protection limits to be adopted by the project are normally agreed through consensus (*e.g.* through a working group of radiation effects experts from the different partner agencies).
- b. The radiation protection limits shall be defined in terms of the protection quantities in Clause [11.2.2](#page-96-0) and the operational quantities in Clause [11.2.3.](#page-98-1)
	- NOTE These limits can vary between different space agencies.
- c. Synergistic effects between radiobiological damage and other environmental stressors and the radiation protection limits specified in [11.4a](#page-99-0) shall be analysed.
	- NOTE 1 Example of such environmental stressors are microgravity, vibration, acceleration, and hypoxia
	- NOTE 2 For guidelines on the influence of spaceflight environment, see ECSS-E-HB-10-12 Section 10.5.7.
- d. The quality factors, radiation weighting factors and tissue weighting factors identified in [Table 11-1,](#page-97-0) [Table 11-2](#page-97-1) and equation [\(3\)](#page-98-0), shall be used to determine dose equivalent, organ equivalent dose and effective dose.
	- NOTE It is the responsibility of the project manager to perform the trade-off between spacecraft and mission design and operation, and their effects on predicted crew exposure, in order to:
		- achieve the defined protection limits, and
		- ensure radiation protection is managed according to the ALARA (as low as reasonably achievable) principle.



# <span id="page-100-1"></span><span id="page-100-0"></span>**11.5 Radiobiological risk assessment**

- a. A radiobiological risk assessment shall be performed by comparing the protection and operational quantities calculated according to the definitions in Clause [11.2](#page-95-0) with the protection limits defined for the project in accordance with requirement [11.4a.](#page-99-1)
- b. When calculating the protection and operational quantities as specified in requirement [11.5a,](#page-100-0) the influence of shielding in attenuating the primary particle environment and modification to its spectrum at the location of the astronaut shall be evaluated as follows:
	- 1. Perform initial calculations as specified in Clause [6.2.2](#page-48-0) to assess the influence of shielding for worst-case shielding, environment and secondary production.
	- 2. If these indicate that the protection limits are exceeded, perform more detailed calculations using a detailed sector shielding calculation or Monte-Carlo analysis, calculation, as specified in Clause[s 6.2.3](#page-50-0) an[d 6.2.4,](#page-51-0) respectively.
- c. The evaluation specified in requirement [11.5b](#page-100-1) shall include the potential variations in radiation exposure as a function of shielding material and its configuration.
- d. Scaling to the equivalent areal mass shall not be performed, unless an analysis is performed that demonstrates that the scaling provides an overestimate of the severity of the environment.
- e. The minimum shielding requirements shall be specified for each mission phase.
	- NOTE The reason is that the shielding issues depend on the mission phase scenario and the associated crew activities within the spacecraft habitats, lunar or planetary habitats, or extravehicular activities.
- f. The crew exposure shall be assessed for all the following:
	- 1. the nominal environment,
	- 2. energetic solar particle events,
	- 3. radiation belt passages, and
	- 4. conditions where the 30-day radiation environment exceeds the nominal environment by a factor of 5.
		- NOTE This is to account for anomalous environmental changes that can affect the 30-day dose limits.
- g. The linear, no threshold (LNT) hypothesis shall be applied extrapolating high-dose-rate data in order to quantify the risk of radiobiological effects.
	- NOTE For long-term missions the doses are likely to attain values where extrapolation can be replaced by a look up into epidemiological data.



- h. If shielding simulations are performed which include self-shielding, the simulation shall include the variations in a build-up of high LET particles, including the nuclear interactions ("star" events) of these particles.
- i. Self-shielding shall be included for simulations where the shielding afforded is less than provided by the self shielding.

NOTE For example, astronauts during an EVA.

- j. For simulation of the effects of self-shielding, secondary radiation generated within an organ shall not be included in the calculation of the equivalent dose to that organ.
	- NOTE 1 The reason is that radiation weighting factors already include secondary particle contribution.
	- NOTE 2 For extremely densely ionising radiation like HZE (high mass and energy) particles and nuclear disintegration stars the concept of absorbed dose can break down and has therefore become inapplicable, but not having better concepts it is the only one used to calculate effective dose or dose equivalent.

# **11.6 Uncertainties**

- a. Analysis of the uncertainties in the exposure calculation shall incorporate the uncertainties in the source data identified in [Table 11-3](#page-102-0) (from the atomic bomb data) and [Table 11-4](#page-102-1) (from the space radiation field).
	- NOTE 1 The uncertainties in risk estimates have been evaluated in detail in 'NCRP 1997' [\[14\].](#page-104-0) The risk estimates are presented in a distribution that ranges from 1,15 to  $8,1x10^{-2}$  Sv<sup>-1</sup> for the 90 % confidence interval for the nominal value of 4 % per Sv for an adult US population.
	- NOTE 2 Uncertainties also arise from systematic errors (and potentially statistical errors in the case of Monte Carlo simulation) in the radiation shielding calculation – see ECSS-E-HB-10-12, Section 5.8.





# <span id="page-102-0"></span>**Table 11-3: Sources of uncertainties for risk estimation from atomic bomb data**

# <span id="page-102-1"></span>**Table 11-4: Uncertainties of risk estimation from the space radiation field**





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